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Resonating-Valence-Bond Liquid in Low Dimensions

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The Hubbard model in D dimensions, with the on-site repulsion U and the transfer integral between nearest neighbors $-t/\sqrt{D}$, is studied on the basis of the Kondo-lattice theory. If $U/|t| \gg 1$, $|n-1| \lesssim |t|/(DU)$, where n is the number of electrons per unit cell, and D is so small that $|J|/D \gg k_B T_c$, where $J = -4t^2/U$ and T_c is 0 K for $D=1$ and is the highest critical temperature among possible ones for $D \geq 2$, a low- T phase where $T_c < T \ll |J|/(k_B D)$ is a frustrated electron liquid. Since the liquid is stabilized by the Kondo effect in conjunction with the resonating-valence-bond (RVB) mechanism, it is simply the RVB electron liquid; in one dimension, it is also the Tomonaga-Luttinger liquid. The Kondo energy of the RVB liquid is $k_B T_K = O(|J|/D)$; its effective Fermi energy is $O(k_B T_K)$. A midband appears on the chemical potential between the upper and lower Hubbard bands; the Hubbard gap is a pseudogap. As regards the density of states per unit cell of the midband, its bandwidth is $O(k_B T_K)$ or $O(|J|/D)$, its peak height is $O(1/U)$, and its spectral weight is $O[t^2/(DU^2)]$. Since the midband almost disappears in the Heisenberg limit, the RVB electron liquid in the Heisenberg limit is simply the RVB spin liquid. The RVB electron and spin liquids adiabatically continue to each other. Since local moments form in a high- T phase where $T \gtrsim T_K$, the high- T phase is simply the Mott insulator.

1. Introduction

A strong electron correlation is one of the most important issues in condensed-matter physics. The Hubbard model is one of the simplest effective Hamiltonians for studying the correlation. The Hubbard model in the Heisenberg limit is equivalent to the Heisenberg model. In the Heisenberg model on the triangular lattice, the resonating-valence-bond (RVB) mechanism is crucial for the stabilization of a frustrated spin liquid, in which no symmetry is broken; the frustrated spin liquid is simply the RVB spin liquid.¹ The RVB mechanism is crucial for not only the triangular lattice but also other types of lattice in sufficiently low dimensions, and in not only the Heisenberg model but also the Hubbard model.² If no symmetry is broken in a strongly correlated electron liquid, the electron liquid is frustrated, as the RVB spin liquid. If a frustrated electron liquid is stabilized by the RVB mechanism, it is simply an RVB electron liquid. It is interesting to study how crucial the RVB mechanism is for the stabilization of a frustrated electron liquid in low dimensions, particularly the Tomonaga-Luttinger (TL) liquid in one dimension.^{3,4}

The Hubbard model in one dimension is of particular interest, because no symmetry is broken in it,⁵ and the Bethe-ansatz solution is available for it.⁶ We consider the thermodynamic limit of $N \rightarrow +\infty$ and $L \rightarrow +\infty$, where N and L are the numbers of electrons and unit cells, respectively. According to the Bethe-ansatz solution,⁶ if the on-site repulsion U is nonzero once, a gap opens in the spectrum of a single-particle excitation in the half-filled ground state with $N=L$; however, no gap opens in any non-half-filled ground state with $N \neq L$. When $T=0$ K, if and only if $N=L$, a metal-insulator (MI) transition occurs at $U=0$ as a function of U . Since no symmetry is broken, the MI transition is never due to a broken symmetry. Lieb and Wu argue that the MI transition at $U=0$ is the Mott transition.⁶ On the other hand, it is expected that the Mott transition will be possible only at a sufficiently large U such that U is as large as the bandwidth, or $U = O(|t|)$, where $|t|$ is the strength of the transfer integral between near-

est neighbors, because it is due to the strong electron correlation.⁷⁻¹⁰

If $U/|t| \gg 1$, the gap $\epsilon_G(U)$ given by the Bethe-ansatz solution is as large as the Hubbard gap;^{8,9} $\epsilon_G(U) = U - O(|t|)$. However, $\epsilon_G(U)$ is so singular at $U=0$ as a function of U that it cannot be expanded in terms of U , as the ground-state energy.¹¹ If $U/|t| \ll 1$, the gap is extremely small. It is doubtful whether the extremely small gap for $U/|t| \ll 1$ is the Hubbard gap. Therefore, it is doubtful whether the MI transition at $U=0$ in one dimension is the Mott transition.

Unless $U/|t| = +\infty$, the residual entropy per unit cell is zero or infinitesimal, depending on N and L ,¹² in the thermodynamic limit; the third law of thermodynamics holds for any finite $U/|t|$, even for the insulating ground state with $N=L$. On the other hand, if $U/|t| = +\infty$, the half-filled ground state is the prototype of the Mott insulator in not only one dimension but also higher dimensions; its residual entropy is $k_B \ln 2$ per unit cell. According to Brinkman-Rice theory,¹⁰ the Mott transition occurs at $U_c = O(|t|)$ and the T -linear specific-heat coefficient diverges as $U \rightarrow U_c - 0$. If no symmetry is broken even for $U \geq U_c$, the divergence means that the residual entropy per unit cell is nonzero for $U \geq U_c$, or for the insulating ground state. In a previous paper,¹³ it is argued that if the ground state is the Mott insulator with no symmetry broken, the third law of thermodynamics is broken in it. In the present paper, the insulating ground state in one dimension is called Lieb and Wu's insulator in order to distinguish it from the Mott insulator.

The number of electrons N is a natural variable in the canonical ensemble. If $N=L$, the ground state is Lieb and Wu's insulator; if $N \neq L$, it is the TL liquid.^{3,4} On the other hand, the chemical potential μ is a natural variable in the grand canonical ensemble. The average number of electrons per unit cell as a function of μ is denoted by $n(\mu)$; it corresponds to N/L . The Bethe-ansatz solution is given for the Hubbard model on a bipartite lattice, which is symmetric under the particle-hole transformation for a particular chemical potential μ_0 ; $n(\mu_0)=1$ for any T . If $|\mu - \mu_0| < (1/2)\epsilon_G(U)$, it is expected that the ground state will be Lieb and Wu's insu-

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lator and $n(\mu)=1$ for it. If $|\mu-\mu_0| \geq (1/2)\epsilon_G(U)$, the ground state is the TL liquid; and $n(\mu) \neq 1$ for any $T \geq 0$ K. If $T > 0$ K once, even if $n(\mu) = 1$, metallic configurations with $N \neq L$ more or less contribute to physical properties statistically averaged in the grand canonical ensemble; thus, in-gap states have to appear even if the ground state is an insulator. An insulator in which a complete gap opens is possible only on the line of $T = 0$ K and $|\mu - \mu_0| < (1/2)\epsilon_G(U)$ in the T - μ phase plane. If T is sufficiently low and $|\mu - \mu_0| \geq (1/2)\epsilon_G(U)$, the TL liquid is stabilized. The phase in the region of $T > 0$ K and $|\mu - \mu_0| < (1/2)\epsilon_G(U)$ is an *intermediate* phase. It is interesting to study whether the *intermediate* phase is insulating or metallic, and how crucial the RVB mechanism is for the stabilization of the *intermediate* phase as well as the TL liquid.

All the single-site terms are rigorously considered in the supreme single-site approximation (S³A).^{14–17} The Kondo-lattice theory (KLT) is a perturbative theory based on S³A to include multisite terms^{18–20} and is also a $1/D$ expansion theory, where D is the dimensionality. The RVB mechanism is a multisite effect and is a higher-order effect in $1/D$. The present paper is an extension of previous study;^{13,21} the RVB mechanism is explicitly considered on the basis of KLT. The main purpose of the present paper is to show that the RVB liquid can be stabilized in sufficiently low dimensions owing to the Kondo effect in conjunction with the RVB mechanism; the RVB liquid in one dimension is also the TL liquid, or the RVB-TL liquid. The present paper is organized as follows: Preliminary is given in Sect. 2. KLT is reviewed in Sect. 3. The RVB liquid is studied on the basis of KLT in Sect. 4. Discussion is given in Sect. 5. Conclusions are given in Sect. 6. A sum rule is proved in Appendix A. An application of the sum rule is given in Appendix B. An equality is proved in Appendix C. It is examined in Appendix D whether, if symmetry breaking is ignored, S³A is rigorous in the limit $1/D \rightarrow 0$.

2. Preliminary

2.1 Hubbard model

We consider the Hubbard model in D dimensions, i.e., on a chain, square, cubic, or hypercubic lattice:

$$\mathcal{H} = \epsilon_d \sum_{i\sigma} n_{i\sigma} - \frac{t}{\sqrt{D}} \sum_{\langle ij \rangle \sigma} d_{i\sigma}^\dagger d_{j\sigma} + U \sum_i n_{i\uparrow} n_{i\downarrow}, \quad (2.1)$$

where $d_{i\sigma}^\dagger$ and $d_{i\sigma}$ are the creation and annihilation operators of an electron with spin σ on the i th unit cell, $n_{i\sigma} = d_{i\sigma}^\dagger d_{i\sigma}$, ϵ_d is the band center, $-t/\sqrt{D}$ is the transfer integral between nearest neighbors and $t > 0$ is assumed, $\langle ij \rangle$ stands for a pair of nearest neighbors, and U is the on-site repulsion. The number of unit cells is L . The thermodynamic limit $L \rightarrow +\infty$ is assumed. The periodic boundary condition is assumed. When $U=0$, the dispersion relation of an electron is given by

$$E(\mathbf{k}) = \epsilon_d - 2t\varphi_D(\mathbf{k}), \quad (2.2)$$

where $\mathbf{k} = (k_1, k_2, \dots, k_D)$ is the wave number, and

$$\varphi_D(\mathbf{k}) = \frac{1}{\sqrt{D}} \sum_{\nu=1}^D \cos(k_\nu a), \quad (2.3)$$

where a is the lattice constant. Because of the factor $1/\sqrt{D}$ in the transfer integral, the effective bandwidth of $E(\mathbf{k})$ is $O(|t|)$ for any D ; the absolute bandwidth is $4\sqrt{D}|t|$.

The number of electrons per unit cell is given by $n(\mu) = \langle \mathcal{N} \rangle / L$, where $\mathcal{N} = \sum_{i\sigma} d_{i\sigma}^\dagger d_{i\sigma}$ and $\langle \cdots \rangle$ stands for the thermal average in the grand canonical ensemble. If the chemical potential μ lies at

$$\mu_0 = \epsilon_d + (1/2)U, \quad (2.4)$$

the Hubbard model is symmetric and half-filled; $n(\mu_0) = 1$ for any T .

2.2 Bethe-ansatz solution for one dimension

2.2.1 Effect of $O(1/L)$ due to electron correlation

We consider one dimension. Since $[\mathcal{H}, \mathcal{N}] = 0$, a many-body eigenstate is specified by the number of electrons N : $\mathcal{N} |N\alpha\rangle = N |N\alpha\rangle$ and $\mathcal{H} |N\alpha\rangle = E_{N\alpha} |N\alpha\rangle$, where α is a set of quantum numbers. In the thermodynamic limit, an infinite number of bosonic excitations, which do not change N , are possible, so that many-body eigenvalues $E_{N\alpha}$ are continuously distributed in the range of

$$E_{Ng} \leq E_{N\alpha} < +\infty, \quad (2.5)$$

where E_{Ng} is the energy of the ground state or the ground-state multiplet, or $|Ng\rangle$. There is no upper limit for $E_{N\alpha}$.

Many-body eigenstates in the presence of a thermal and/or electron reservoir are more or less different from those in the absence of it. We assume that this difference can be ignored.

We assume that $T = 0$ K in the canonical ensemble. The retarded Green function in the site representation is given by

$$R_{ij\sigma}^{(N)}(\varepsilon + i0) = \frac{1}{v_N} \sum_g R_{ij\sigma}^{(Ng)}(\varepsilon + i0), \quad (2.6)$$

where the summation is over the ground-state multiplet and v_N is its degeneracy, and

$$R_{ij\sigma}^{(N\alpha)}(z) = \sum_\beta \left\{ \frac{\langle N\alpha | a_{i\sigma} | (N+1)\beta \rangle \langle (N+1)\beta | a_{j\sigma}^\dagger | N\alpha \rangle}{z - [E_{(N+1)\beta} - E_{N\alpha}]} + \frac{\langle N\alpha | a_{j\sigma}^\dagger | (N-1)\beta \rangle \langle (N-1)\beta | a_{i\sigma} | N\alpha \rangle}{z - [E_{N\alpha} - E_{(N-1)\beta}]} \right\}. \quad (2.7)$$

The site-diagonal Green function is given by

$$R_\sigma^{(N)}(\varepsilon + i0) = \frac{1}{v_N} \sum_g \int_{-\infty}^{+\infty} d\varepsilon' \frac{D_{Ng}(\varepsilon')}{\varepsilon + i0 - \varepsilon'}, \quad (2.8)$$

$$D_{N\alpha}(\varepsilon) = \sum_\beta |\langle (N+1)\beta | a_{i\sigma}^\dagger | N\alpha \rangle|^2 \delta[\varepsilon - E_{(N+1)\beta} + E_{N\alpha}] + \sum_\beta |\langle (N-1)\beta | a_{i\sigma} | N\alpha \rangle|^2 \delta[\varepsilon - E_{N\alpha} + E_{(N-1)\beta}]. \quad (2.9)$$

Neither $R_\sigma^{(N)}(\varepsilon + i0)$ nor $D_{N\alpha}(\varepsilon)$ depends on the unit cell. The density of states per unit cell is given by

$$\rho_N(\varepsilon) = -\frac{1}{\pi} \text{Im} R_\sigma^{(N)}(\varepsilon + i0) = \frac{1}{v_N} \sum_g D_{Ng}(\varepsilon). \quad (2.10)$$

Two types of *Fermi level* are defined: $\mu_+(N) = E_{(N+1)g} - E_{Ng}$ for the addition of an electron and $\mu_-(N) = E_{Ng} - E_{(N-1)g}$ for the removal of an electron. According to the Bethe-ansatz solution,⁶ if $N \neq L$, $[\mu_+(N) - \mu_-(N)] \rightarrow 0$ as $L \rightarrow +\infty$. No gap opens in $\rho_{N \neq L}(\varepsilon)$. The ground state is the TL liquid for any non-half filling.^{3,4} Either $\rho_{N \neq L}(\varepsilon)$ or

$D_{N \neq L\alpha}(\varepsilon)$ is more or less nonzero for any ε .²²

On the other hand, if and only if $N = L$,

$$\varepsilon_G(U) = \mu_+(L) - \mu_-(L) \quad (2.11)$$

is nonzero even in the limit $L \rightarrow +\infty$; $\mu_{\pm}(L) = \mu_0 \pm (1/2)\varepsilon_G(U)$. Then, $\varepsilon_G(U)$ is simply a gap in $\rho_L(\varepsilon)$. The half-filled ground state is Lieb and Wu's insulator. It is easy to see that $\rho_L(\varepsilon) = 0$ and $D_{Lg}(\varepsilon) = 0$ for $|\varepsilon - \mu_0| < (1/2)\varepsilon_G(U)$. We define $\Delta E_{L\alpha} = E_{L\alpha} - E_{Lg}$. If $\Delta E_{L\alpha} < (1/2)\varepsilon_G(U)$, then $D_{L\alpha}(\varepsilon) = 0$ for $|\varepsilon - \mu_0| < (1/2)\varepsilon_G(U) - \Delta E_{L\alpha}$, but $D_{L\alpha}(\varepsilon) > 0$ for $|\varepsilon - \mu_0| \geq (1/2)\varepsilon_G(U) - \Delta E_{L\alpha}$. If $\Delta E_{L\alpha} \geq (1/2)\varepsilon_G(U)$, then $D_{L\alpha}(\varepsilon) > 0$ for any ε . Thus, $D_{L\alpha}(\varepsilon) > 0$ at least for certain α 's, regardless of ε .

As a function of N , $\rho_N(\varepsilon)$ is *discontinuous* between $N = L$ and $N = L \pm 1$, or between Lieb and Wu's insulator and the TL liquid. This *discontinuous* behavior is different from the *continuous* behavior between Wilson's band insulator and metal. The opening of $\varepsilon_G(U)$ and the *discontinuous* behavior of $\rho_N(\varepsilon)$ are different appearances of an effect due to the difference in electron correlation between $N = L$ and $N = L \pm 1$. The effect is an effect of $O(1/N)$ or $O(1/L)$ due to electron correlation.

2.2.2 Rigidity of Lieb and Wu's insulator

If many-body eigenstates of the Bethe-ansatz solution are used, the thermal Green function is given by

$$R_{ij\sigma}(i\varepsilon_l) = \sum_{N\alpha} p_{N\alpha}(T) R_{ij\sigma}^{(N\alpha)}(i\varepsilon_l + \mu), \quad (2.12)$$

where $\varepsilon_l = (2l+1)\pi k_B T$, with l being an integer, $R_{ij\sigma}^{(N\alpha)}(z)$ is defined by Eq. (2.7), μ is the chemical potential, and

$$p_{N\alpha}(T) = \frac{\exp[-(E_{N\alpha} - \mu N)/(k_B T)]}{\sum_{N'\alpha'} \exp[-(E_{N'\alpha'} - \mu N')/(k_B T)]}. \quad (2.13)$$

The site-diagonal thermal Green function is given by

$$R_{\sigma}(i\varepsilon_l) = \sum_{N\alpha} p_{N\alpha}(T) \int_{-\infty}^{+\infty} d\varepsilon' \frac{D_{N\alpha}(\varepsilon')}{i\varepsilon_l + \mu - \varepsilon'}. \quad (2.14)$$

The density of states per unit cell is given by

$$\rho_{\mu}(\varepsilon) = -\frac{1}{\pi} \text{Im} R_{\sigma}(\varepsilon + i0) = \sum_{N\alpha} p_{N\alpha}(T) D_{N\alpha}(\varepsilon + \mu). \quad (2.15)$$

The average number of electrons per unit cell is given by

$$n(\mu) = \frac{1}{L} \sum_{N\alpha} p_{N\alpha}(T) N = \int_{-\infty}^{+\infty} d\varepsilon \frac{\rho_{\mu}(\varepsilon)}{e^{\varepsilon/(k_B T)} + 1}. \quad (2.16)$$

We assume that $|\mu - \mu_0| < (1/2)\varepsilon_G(U)$. If $T = 0$ K,

$$\rho_{\mu}(\varepsilon) = \rho_L(\mu + \varepsilon). \quad (2.17)$$

Then, $\rho_{\mu}(\varepsilon) = 0$ for $|\varepsilon + \mu - \mu_0| < (1/2)\varepsilon_G(U)$. The ground state is Lieb and Wu's insulator. It follows that

$$R_{\sigma}(\varepsilon + i0) = -\frac{1}{\pi} \int_{-\infty}^{+\infty} d\varepsilon' \frac{\rho_L(\mu + \varepsilon')}{\varepsilon - \varepsilon' + i0}. \quad (2.18)$$

Since $\rho_L(\varepsilon)$ does not depend on μ , neither $\rho_{\mu}(\varepsilon - \mu)$ nor $R_{\sigma}(\varepsilon - \mu + i0)$ depends on μ . Lieb and Wu's insulator is *rigid* against the movement of μ ,²³ as Wilson's band insulator. This is simply because many-body eigenstates in the absence of a reservoir are used and the reservoir effect is only implicitly

treated through the statistical average or the probability function $p_{N\alpha}(T)$. The relevance of this treatment is critically examined in Sect. 5.2.

The static homogeneous charge susceptibility or the compressibility is given by

$$\chi_c(0,0) = dn(\mu)/d\mu. \quad (2.19)$$

Because of the *rigidity*, $\chi_c(0,0) = 0$ for $|\mu - \mu_0| < (1/2)\varepsilon_G(U)$, or for Lieb and Wu's insulator.

2.2.3 Discontinuous MI transition at $T = 0$ K

We assume that $T = 0$ K in the grand canonical ensemble. An MI transition occurs at $\mu = \mu_0 \pm (1/2)\varepsilon_G(U)$ as a function of μ . If $|\mu - \mu_0| < (1/2)\varepsilon_G(U)$, the ground state is Lieb and Wu's insulator and no Fermi *surface* exists. Since no density wave appears, no folding of the Brillouin zone occurs. The absence of the Fermi *surface* means that its *volume* or size is absolutely zero in either the particle or hole picture.²⁴ If $|\mu - \mu_0| > (1/2)\varepsilon_G(U)$, the ground state is the TL liquid and the Fermi *surface* exists. According to the Fermi-surface sum rule,^{25,26} the sizes of the Fermi *surface* are $2|k_F| = (\pi/a)n(\mu)$ and $2|k_F| = (\pi/a)[2 - n(\mu)]$ in the electron and hole pictures, respectively, where k_F is the Fermi wave number in each picture. For example, if $\mu = \mu_0 + (1/2)\varepsilon_G(U) - 0^+$, the size of the Fermi *surface* is zero in either picture and $\rho_{\mu}(\varepsilon) = 0$ for $-\varepsilon_G(U) < \varepsilon < 0$. If $\mu = \mu_0 + (1/2)\varepsilon_G(U) + 0^+$, the size of the Fermi *surface* is $2|k_F| = \pi/a$ in either picture and $\rho_{\mu}(\varepsilon) > 0$ even for $-\varepsilon_G(U) < \varepsilon < 0$. These discontinuous behaviors mean that the MI transition is discontinuous.

The compressibility $\chi_c(0,0)$ is also discontinuous at $\mu = \mu_0 \pm (1/2)\varepsilon_G(U)$ at least in the limit $U/|t| \rightarrow +\infty$, as studied below. As preliminary, we consider many-body eigenstates in the limit $U/|t| \rightarrow +\infty$. If $N \leq L$, no double occupancy at a unit cell is allowed. Every many-body eigenstate is specified by the set of N pairs of wave number and spin, $\{k\sigma\} = \{k_1\sigma_1, k_2\sigma_2, \dots, k_N\sigma_N\}$. Its eigenfunction is the direct product of the charge part, which is a single Slater determinant of noninteracting N spinless fermions, and the spin part, which is a product of spin functions of noninteracting N spins:

$$|N\{k\sigma\}\rangle = \sum_{\{xs\}} \Phi_{\{k\sigma\}}(\{xs\}) a_{x_1s_1}^{\dagger} a_{x_2s_2}^{\dagger} \cdots a_{x_Ns_N}^{\dagger} |0\rangle, \quad (2.20)$$

$$\Phi_{\{k\sigma\}}(\{xs\}) = \frac{1}{\sqrt{N!}} \sum_P (-1)^P \prod_{i=1}^N \frac{1}{\sqrt{L}} e^{ik_{P_i}x_i} \prod_{j=1}^N \chi_{\sigma_j}(s_j), \quad (2.21)$$

where $|0\rangle$ is the vacuum where no electron exists, $\{x\sigma\} = \{(x_1, s_1), (x_2, s_2), \dots, (x_N, s_N)\}$ with $0 \leq x_1 < x_2 < \dots < x_N \leq La$ is the set of the position and spin coordinates of N electrons, $P = (P_1, P_2, \dots, P_N)$ is an N -permutation, $(-1)^P = 1$ for an even P while $(-1)^P = -1$ for an odd P , and $\chi_{\sigma}(s)$ is the spin function for $S = 1/2$. Its eigenenergy is given by $E_{\{k\sigma\}} = \sum_{i=1}^N E(k_i)$. If $N = L$, the spinless fermion band is completely filled and the electron state is the prototype of the Mott insulator. If $N \neq L$, the spinless fermion band is partially filled and the electron state is an exotic metal such that a complete charge-spin separation occurs in it and its ground-state degeneracy is 2^N . If the hole picture is taken, a similar argument is possible for $N \geq L$.

We consider the limit $U/|t| \rightarrow +\infty$ in the grand canonical

cal ensemble. If $n(\mu) = 1$, which corresponds to $N = L$, $\chi_c(0, 0) = 0$. If $n(\mu) \simeq 1$ but $n(\mu) \neq 1$, which corresponds to $N \simeq L$ but $N \neq L$, $\chi_c(0, 0) \propto 1/|1 - n(\mu)|$. Thus, $\chi_c(0, 0)$ diverges as $n(\mu) \rightarrow 1$, i.e., $\chi_c(0, 0)$ diverges as $\mu \rightarrow \mu_0 \pm (1/2)\epsilon_G(U) \pm 0$; this divergence is due to the band-edge van Hove singularity in the one-dimensional dispersion relation of the noninteracting spinless fermion. The compressibility $\chi_c(0, 0)$ is discontinuous at $\mu = \mu_0 \pm (1/2)\epsilon_G(U)$ as a function of μ at least in the limit $U/|t| \rightarrow +\infty$.

If $U/|t|$ is finite and $n(\mu) \simeq 1$ but $n(\mu) \neq 1$, the Fermi surface as large as $2|k_F| \simeq (\pi/a)$ exists in either the particle or hole picture. The existence of such a large Fermi surface implies that $\chi_c(0, 0)$ is more or less nonzero. Moreover, the divergence of $\chi_c(0, 0)$ in the limit $U/|t| \rightarrow +\infty$ implies that the increase in $\chi_c(0, 0)$ occurs as $\mu \rightarrow \mu_0 \pm (1/2)\epsilon_G(U) \pm 0$ at least for a sufficiently large $U/|t|$. It is interesting to determine whether $\chi_c(0, 0)$ continuously becomes zero as $\mu \rightarrow \mu_0 \pm (1/2)\epsilon_G(U) \pm 0$ or discontinuously becomes zero at $\mu = \mu_0 \pm (1/2)\epsilon_G(U)$, and whether $\chi_c(0, 0)$ increases as $\mu \rightarrow \mu_0 \pm (1/2)\epsilon_G(U) \pm 0$.

2.2.4 In-gap states at $T > 0$ K

We assume that $T > 0$ K. Then, $p_{N\alpha}(T)$ defined by Eq. (2.13) is more or less nonzero. If $N \neq L$, $D_{N\alpha}(\varepsilon)$ defined by Eq. (2.9) is nonzero; even if $N = L$, $D_{L\alpha}(\varepsilon) > 0$ for certain α 's, regardless of ε . The density of states $\rho_\mu(\varepsilon)$ given by Eq. (2.15) is more or less nonzero,²² even for $|\varepsilon + \mu - \mu_0| < (1/2)\epsilon_G(U)$. It is straightforward to show that the density of states is also more or less nonzero in the canonical ensemble.

The gap opens only in the *exactly* half-filled case at $T = 0$ K. If the filling is non-half or $T > 0$ K once, the effect of $O(1/L)$ disappears or becomes insufficient for the gap to open, in either the canonical or grand canonical ensembles.

3. Kondo-Lattice Theory

3.1 Single-site properties of the Hubbard model

3.1.1 Mapping to the Anderson model

In Sect. 3, we review KLT,^{18–21} and reformulate it in a form appropriate for the present study. We assume that $T > T_c$, where T_c is 0 K for $D=1$ and is the highest critical temperature among possible ones for $D \geq 2$. If $T > T_c$, $\rho_\mu(\varepsilon)$ is more or less nonzero at least for $|\varepsilon| < |t|$,²² and even in one dimension. The fact that $\rho_\mu(\varepsilon)$ is necessarily nonzero for $T > T_c$ is crucial in the present study.

If $T > T_c$, no symmetry is broken and no gap opens; thus, there is no doubt on the validity of the perturbative treatment in terms of U based on the Feynman-diagram method.²⁷ We consider a connected and irreducible Feynman diagram for a physical property. The diagram is composed of electron lines, each of which stands for $R_{ij\sigma}(i\varepsilon_l)$, and interaction lines, each of which stands for U . The site-diagonal $R_{ii\sigma}(i\varepsilon_l)$ is simply denoted by $R_\sigma(i\varepsilon_l)$. If only site-diagonal $R_\sigma(i\varepsilon_l)$'s appear in the diagram, it is a single-site diagram; if at least a site-off-diagonal $R_{i \neq j \sigma}(i\varepsilon_l)$ appears in the diagram, it is a multisite diagram. The diagram can be classified into a single-site or multisite diagram. The physical property is decomposed into the single-site term, which is the sum of all the single-site diagrams, and the multisite term, which is the sum of all the multisite diagrams.

The self-energy in the site representation is defined by

$$R_{ij\sigma}(i\varepsilon_l) = R_{ij\sigma}^{(0)}(i\varepsilon_l) + \sum_{i'j'} R_{ii'\sigma}^{(0)}(i\varepsilon_l) \Sigma_{i'j'\sigma}(i\varepsilon_l) R_{j'j\sigma}(i\varepsilon_l), \quad (3.1)$$

where $\Sigma_{ij\sigma}(i\varepsilon_l)$ is the self-energy and

$$R_{ij\sigma}^{(0)}(i\varepsilon_l) = \frac{1}{L} \sum_{\mathbf{k}} e^{i\mathbf{k} \cdot (\mathbf{R}_i - \mathbf{R}_j)} \frac{1}{i\varepsilon_l + \mu - E(\mathbf{k})} \quad (3.2)$$

is the Green function for $U = 0$; $\mathbf{R}_i$ is the position of the i th unit cell. The self-energy $\Sigma_{ij\sigma}(i\varepsilon_l)$ is decomposed into the single-site $\delta_{ij}\Sigma_\sigma(i\varepsilon_l)$ and the multisite $\Delta\Sigma_{ij\sigma}(i\varepsilon_l)$:

$$\Sigma_{ij\sigma}(i\varepsilon_l) = \delta_{ij}\Sigma_\sigma(i\varepsilon_l) + \Delta\Sigma_{ij\sigma}(i\varepsilon_l). \quad (3.3)$$

The single-site $\Sigma_\sigma(i\varepsilon_l)$ does not depend on the unit cell.

The site-diagonal $R_\sigma(i\varepsilon_l)$ and the single-site $\Sigma_\sigma(i\varepsilon_l)$ are local properties. It is possible to map them to their corresponding local properties of an appropriate impurity model. The appropriate impurity model is the Anderson model.^{18–20}

We consider the Anderson model defined by

$$\begin{aligned} \tilde{\mathcal{H}} = & \tilde{\epsilon}_d \sum_{\sigma} n_{d\sigma} + \sum_{\mathbf{k}\sigma} E_c(\mathbf{k}) c_{\mathbf{k}\sigma}^\dagger c_{\mathbf{k}\sigma} + \tilde{U} n_{d\uparrow} n_{d\downarrow} \\ & + \frac{1}{\tilde{L}} \sum_{\mathbf{k}\sigma} \left(V_{\mathbf{k}} c_{\mathbf{k}\sigma}^\dagger d_{\sigma} + V_{\mathbf{k}}^* d_{\sigma}^\dagger c_{\mathbf{k}\sigma} \right), \end{aligned} \quad (3.4)$$

where $n_{d\sigma} = d_{\sigma}^\dagger d_{\sigma}$, $\tilde{\epsilon}_d$ is the level of d electrons, $E_c(\mathbf{k})$ is the dispersion relation of conduction electrons, $\tilde{U}$ is the on-site repulsion, $\tilde{L}$ is the number of unit cells, and $V_{\mathbf{k}}$ is the hybridization matrix between conduction and d electrons. In the present paper, the temperature of the reservoir for the Anderson model is denoted by $\tilde{T}$ and treated as a parameter independent of T for the Hubbard model. The Green function for d electrons is given by

$$\tilde{G}_\sigma(i\tilde{\varepsilon}_l) = \frac{1}{i\tilde{\varepsilon}_l + \tilde{\mu} - \tilde{\epsilon}_d - \tilde{\Sigma}_\sigma(i\tilde{\varepsilon}_l) - \tilde{\Gamma}(i\tilde{\varepsilon}_l)}, \quad (3.5)$$

$$\tilde{\Gamma}(i\tilde{\varepsilon}_l) = \frac{1}{\pi} \int_{-\infty}^{+\infty} d\varepsilon' \frac{\Delta(\varepsilon')}{i\tilde{\varepsilon}_l - \varepsilon'}, \quad (3.6)$$

$$\Delta(\varepsilon) = -\text{Im}\tilde{\Gamma}(\varepsilon + i0) = \frac{\pi}{\tilde{L}} \sum_{\mathbf{k}} |V_{\mathbf{k}}|^2 \delta[\varepsilon + \tilde{\mu} - E_c(\mathbf{k})], \quad (3.7)$$

where $\tilde{\varepsilon}_l = (2l+1)\pi k_B \tilde{T}$, with l being an integer, and $\tilde{\Sigma}_\sigma(i\tilde{\varepsilon}_l)$ is the self-energy for d electrons. The Anderson model is essentially uniquely characterized by the four parameters $\tilde{T}$, $\tilde{U}$, $\tilde{\epsilon}_d - \tilde{\mu}$, and $\Delta(\varepsilon)$; none of the arbitrariness of $\tilde{\epsilon}_d$, $\tilde{\mu}$, $V_{\mathbf{k}}$, or $E_c(\mathbf{k})$ is crucial. The four parameters have to be determined to satisfy an appropriate mapping condition.

Since $\tilde{\Sigma}_\sigma(i\tilde{\varepsilon}_l)$ is a local term, only $\tilde{U}$ and $\tilde{G}_\sigma(i\tilde{\varepsilon}_l)$ appear in any Feynman diagram for $\tilde{\Sigma}_\sigma(i\tilde{\varepsilon}_l)$ of the Anderson model; only U and $R_\sigma(i\varepsilon_l)$ appear in any Feynman diagram for the single-site $\Sigma_\sigma(i\varepsilon_l)$ of the Hubbard model. Provided that

$$T = \tilde{T}, \quad U = \tilde{U}, \quad (3.8a)$$

$$R_\sigma(i\varepsilon_l) = \tilde{G}_\sigma(i\tilde{\varepsilon}_l) \quad (3.8b)$$

are satisfied, it immediately follows that

$$\Sigma_\sigma(i\varepsilon_l) = \tilde{\Sigma}_\sigma(i\tilde{\varepsilon}_l). \quad (3.9)$$

Equation (3.8) is the appropriate mapping condition. At least

$$\epsilon_d - \mu = \tilde{\epsilon}_d - \tilde{\mu} \quad (3.10)$$

has to be satisfied in order that Eq. (3.8b) can be satisfied. Then, it immediately follows that²⁰

$$\Delta(\epsilon) = \text{Im} \left[\tilde{\Sigma}_\sigma(\epsilon + i0) + 1/R_\sigma(\epsilon + i0) \right]. \quad (3.11)$$

If all of Eqs. (3.8a) and (3.10), and

$$\Delta(\epsilon) = \text{Im} [\Sigma_\sigma(\epsilon + i0) + 1/R_\sigma(\epsilon + i0)] \quad (3.12)$$

are satisfied, Eqs. (3.9) and (3.11) are satisfied. We can substitute Eq. (3.12) for Eq. (3.11). The set of Eqs. (3.8a), (3.10), and (3.12) is the mapping condition; Eq. (3.12) is a practical mapping condition because the others are simple.

It should be noted that $\Delta(\epsilon)$ given by Eq. (3.12) depends on the temperature T of the reservoir for the Hubbard model. The mapped Anderson model itself includes T as a *parameter*.

There is no doubt on the possibility that, if the Hubbard model is solved once, the four parameters $\tilde{T}$, $\tilde{U}$, $\tilde{\epsilon}_d - \tilde{\mu}$, and $\Delta(\epsilon)$ of the Anderson model can be uniquely determined from the mapping condition. All pairs of corresponding properties are exactly equal to each other between the Hubbard and Anderson models; e.g., $\Sigma_\sigma(\epsilon + i0) = \tilde{\Sigma}_\sigma(\epsilon + i0)$, $R_\sigma(\epsilon + i0) = \tilde{G}_\sigma(\epsilon + i0)$, $n(\mu) = \tilde{n}(\tilde{\mu})$, $\rho_\mu(\epsilon) = \tilde{\rho}(\tilde{\epsilon})$, and so on, where $\tilde{n}(\tilde{\mu}) = \langle n_{d\uparrow} + n_{d\downarrow} \rangle$ and

$$\tilde{\rho}(\tilde{\epsilon}) = -(1/\pi) \text{Im} \tilde{G}_\sigma(\tilde{\epsilon} + i0). \quad (3.13)$$

If $\mu = \mu_0$, the Anderson model is also symmetric.

The Green function for the Hubbard model in the wave-number representation is given by

$$\begin{aligned} G_\sigma(i\epsilon_l, \mathbf{k}) &= \frac{1}{L} \sum_{ij} e^{-i\mathbf{k} \cdot (\mathbf{R}_i - \mathbf{R}_j)} R_{ij\sigma}(i\epsilon_l) \\ &= \frac{1}{i\epsilon_l + \mu - E(\mathbf{k}) - \Sigma_\sigma(i\epsilon_l, \mathbf{k})}, \end{aligned} \quad (3.14)$$

$$\Sigma_\sigma(i\epsilon_l, \mathbf{k}) = \Sigma_\sigma(i\epsilon_l) + \Delta\Sigma_\sigma(i\epsilon_l, \mathbf{k}), \quad (3.15)$$

$$\Delta\Sigma_\sigma(i\epsilon_l, \mathbf{k}) = \frac{1}{L} \sum_{ij} e^{-i\mathbf{k} \cdot (\mathbf{R}_i - \mathbf{R}_j)} \Delta\Sigma_{ij\sigma}(i\epsilon_l). \quad (3.16)$$

Here, $\Sigma_\sigma(i\epsilon_l, \mathbf{k})$, $\Sigma_\sigma(i\epsilon_l)$, and $\Delta\Sigma_\sigma(i\epsilon_l, \mathbf{k})$ are the total, single-site, and multisite self-energies, respectively.

The theory reviewed and reformulated above is KLT.^{18–21} Multisite terms have to be self-consistently considered with the Anderson model to be mapped. If no multisite term is considered in KLT, it is reduced to S³A.^{14–17} Either the dynamical mean-field theory^{28,29} (DMFT) or the dynamical coherent-potential approximation³⁰ (DCPA) is also S³A.

3.1.2 Nonzero and finite $\Delta(\epsilon)$ of the Anderson model

The purpose of Sect. 3.1.2 is to show that if $T > T_c$,

$$0 < \Delta(\epsilon) < +\infty \quad (3.17)$$

has to be satisfied in any self-consistent solution of KLT, in which $\rho_\mu(\epsilon) > 0$ is necessarily satisfied. We refer to a previous paper.²¹ We define two real functions:

$$Y_n(\epsilon) = \frac{1}{L} \sum_{\mathbf{k}} \frac{S_1^n(\epsilon, \mathbf{k})}{S_1^2(\epsilon, \mathbf{k}) + S_2^2(\epsilon, \mathbf{k})}, \quad (3.18a)$$

$$Z_n(\epsilon) = \frac{1}{L} \sum_{\mathbf{k}} \frac{S_2^n(\epsilon, \mathbf{k})}{S_1^2(\epsilon, \mathbf{k}) + S_2^2(\epsilon, \mathbf{k})}, \quad (3.18b)$$

where $S_1(\epsilon, \mathbf{k}) = \text{Re}[1/G_\sigma(\epsilon + i0, \mathbf{k})]$ and $S_2(\epsilon, \mathbf{k}) = \text{Im}[1/G_\sigma(\epsilon + i0, \mathbf{k})]$. It follows that

$$Y_0(\epsilon) = Z_0(\epsilon), \quad (3.19)$$

$$R_\sigma(\epsilon + i0) = Y_1(\epsilon) - iZ_1(\epsilon), \quad (3.20)$$

$$Z_1(\epsilon) = \pi\rho_\mu(\epsilon) > 0, \quad (3.21)$$

$$Y_2(\epsilon) + Z_2(\epsilon) = 1. \quad (3.22)$$

Since either of

$$\frac{1}{L} \sum_{\mathbf{k}} \frac{[x + S_1(\epsilon, \mathbf{k})]^2}{S_1^2(\epsilon, \mathbf{k}) + S_2^2(\epsilon, \mathbf{k})} = Y_0(\epsilon)x^2 + 2Y_1(\epsilon)x + Y_2(\epsilon), \quad (3.23a)$$

$$\frac{1}{L} \sum_{\mathbf{k}} \frac{[x + S_2(\epsilon, \mathbf{k})]^2}{S_1^2(\epsilon, \mathbf{k}) + S_2^2(\epsilon, \mathbf{k})} = Y_0(\epsilon)x^2 + 2Z_1(\epsilon)x + Z_2(\epsilon), \quad (3.23b)$$

cannot be negative for any real x ,³¹ it follows that

$$-Y_1^2(\epsilon) + Y_0(\epsilon)Y_2(\epsilon) \geq 0, \quad (3.24a)$$

$$-Z_1^2(\epsilon) + Z_0(\epsilon)Z_2(\epsilon) \geq 0. \quad (3.24b)$$

The perturbative analysis in terms of U is useful for $U/|t| \ll 1$; that in terms of $J = -4t^2/U$ based on KLT is useful for $U/|t| \gg 1$, as demonstrated in Sect. 4. In either analysis, it is easy to find terms that give a nonzero contribution to $\text{Im}\Sigma_\sigma(\epsilon + i0)$ or $\text{Im}\Delta\Sigma_\sigma(\epsilon + i0, \mathbf{k})$, provided that $T > 0$ K and $\rho_\mu(\epsilon) > 0$. If $T > T_c$, then $\rho_\mu(\epsilon) > 0$, so that

$$0 < -\text{Im}\Sigma_\sigma(\epsilon + i0) < -\text{Im}\Sigma_\sigma(\epsilon + i0, \mathbf{k}). \quad (3.25)$$

Then, $Y_1(\epsilon)$ is finite and $Z_1(\epsilon)$ is nonzero and finite, so that

$$0 < Y_1^2(\epsilon) + Z_1^2(\epsilon) < +\infty. \quad (3.26)$$

First, we show that $\Delta(\epsilon)$ cannot be positively divergent. If Eq. (3.20) is used, Eq. (3.12) can be described as

$$\Delta(\epsilon) = \text{Im}\Sigma_\sigma(\epsilon + i0) + Z_1(\epsilon)/[Y_1^2(\epsilon) + Z_1^2(\epsilon)]. \quad (3.27)$$

In general, $\text{Im}\Sigma_\sigma(\epsilon + i0) \leq 0$. According to Eq. (3.21) or (3.26), $Z_1(\epsilon)/[Y_1^2(\epsilon) + Z_1^2(\epsilon)] < +\infty$. Then, $\Delta(\epsilon) < +\infty$.

Next, we show that $\Delta(\epsilon)$ has to be nonzero and positive. If Eq. (3.22) is used, Eq. (3.27) can be described as

$$\Delta(\epsilon) = X(\epsilon)/[Y_1^2(\epsilon) + Z_1^2(\epsilon)], \quad (3.28)$$

$$\begin{aligned} X(\epsilon) &= \text{Im}\Sigma_\sigma(\epsilon + i0) [Y_1^2(\epsilon) + Z_1^2(\epsilon)] \\ &\quad + Z_1(\epsilon) [Y_2(\epsilon) + Z_2(\epsilon)]. \end{aligned} \quad (3.29)$$

According to Eqs. (3.18b) and (3.25),

$$Z_1(\epsilon) > -\text{Im}\Sigma_\sigma(\epsilon + i0)Z_0(\epsilon). \quad (3.30)$$

According to Eqs. (3.19), (3.29), and (3.30),

$$\begin{aligned} X(\epsilon) &> -\text{Im}\Sigma_\sigma(\epsilon + i0) \{ [-Y_1^2(\epsilon) + Y_0(\epsilon)Y_2(\epsilon)] \\ &\quad + [-Z_1^2(\epsilon) + Z_0(\epsilon)Z_2(\epsilon)] \}. \end{aligned} \quad (3.31)$$

According to Eqs. (3.24), (3.25), and (3.31), it follows that $X(\epsilon) > 0$. According to $X(\epsilon) > 0$ and Eqs. (3.26) and (3.28), it follows that $\Delta(\epsilon) > 0$. Thus, Eq. (3.17) has to be satisfied.

Since $\Delta(\varepsilon) < +\infty$, $\tilde{\Gamma}(\varepsilon + i0)$ can have no pole on the real axis in any self-consistent solution of KLT for $T > T_c$.

3.1.3 Polarization and vertex functions in the spin channel

Here, we refer to previous papers.³²⁻³⁴ The bosonic energy is denoted by $\omega_l = 2l\pi k_B T$, with l being an integer. In the wave-number representation, the irreducible polarization function $\pi_s(i\omega_l, \mathbf{q})$ in the spin channel is decomposed into the single-site $\pi_s(i\omega_l)$ and the multisite $\Delta\pi_s(i\omega_l, \mathbf{q})$:

$$\pi_s(i\omega_l, \mathbf{q}) = \pi_s(i\omega_l) + \Delta\pi_s(i\omega_l, \mathbf{q}). \quad (3.32)$$

The single-site $\pi_s(i\omega_l)$ is equal to the local $\tilde{\pi}_s(i\omega_l)$ of the Anderson model: $\pi_s(i\omega_l) = \tilde{\pi}_s(i\omega_l)$. The spin susceptibilities of the Anderson and Hubbard models are given by

$$\tilde{\chi}_s(i\omega_l) = 2\tilde{\pi}_s(i\omega_l)/[1 - U\tilde{\pi}_s(i\omega_l)], \quad (3.33a)$$

$$\chi_s(i\omega_l, \mathbf{q}) = 2\pi_s(i\omega_l, \mathbf{q})/[1 - U\pi_s(i\omega_l, \mathbf{q})], \quad (3.33b)$$

respectively. Here, the conventional factor $(1/4)g^2\mu_B^2$ is not included, where g is the g factor and μ_B is the Bohr magneton. The susceptibility $\tilde{\chi}_s(i\omega_l)$ of the Anderson model includes no contribution from the polarization of conduction electrons.

The Kondo temperature or energy is defined by

$$[\tilde{\chi}_s(0; T)]_{\tilde{T}=0 \text{ K}} = 1/[k_B T_K(T)], \quad (3.34)$$

where $\tilde{T} = 0 \text{ K}$ means that the temperature of the reservoir for the Anderson model is the absolute zero Kelvin; T of the reservoir for the Hubbard model or the *parameter* T is explicitly shown because $\tilde{\chi}_s(0; T)$ and $T_K(T)$ depend on T . Although this definition of T_K is different from Wilson's³⁵ by a numerical factor, $k_B T_K$ is still a measure of the magnitude of stabilization energy. Since $\tilde{\rho}(\varepsilon) = \rho_\mu(\varepsilon) > 0$ and $0 < \Delta(\varepsilon) < +\infty$ for $T > T_c$, $k_B T_K > 0$ and never $k_B T_K = 0$ in any self-consistent solution of KLT for $T > T_c$.

The formulation so far is valid for any finite $U/|t|$. The formulation in the following part is only valid for $U/|t| \gg 1$. If $U/|t| \gg 1$, then $k_B T_K/U \ll 1$;

$$\tilde{\chi}_s(i\omega_l) = O[1/(k_B T_K)], \quad (3.35a)$$

$$\chi_s(i\omega_l, \mathbf{q}) = O[1/(k_B T_K)], \quad (3.35b)$$

for $T \lesssim T_K$ and $|\omega_l| \lesssim k_B T_K$. According to Eqs. (3.33) and (3.35), $U\tilde{\pi}_s(i\omega_l) = 1 + O(k_B T_K/U)$, $U\pi_s(i\omega_l, \mathbf{q}) = 1 + O(k_B T_K/U)$, and $U^2\Delta\pi_s(i\omega_l, \mathbf{q}) = O[(k_B T_K/U)^0]$. Then,

$$U[1 - U\tilde{\pi}_s(i\omega_l)] = 2/\tilde{\chi}_s(i\omega_l), \quad (3.36)$$

$$\chi_s(i\omega_l, \mathbf{q}) = \frac{\tilde{\chi}_s(i\omega_l)}{1 - (1/4)I_s(i\omega_l, \mathbf{q})\tilde{\chi}_s(i\omega_l)}, \quad (3.37)$$

for $T \lesssim T_K$ and $|\omega_l| \lesssim k_B T_K$, where

$$I_s(i\omega_l, \mathbf{q}) = 2U^2\Delta\pi(i\omega_l, \mathbf{q}). \quad (3.38)$$

Here, the terms of $O(k_B T_K/U)$ are ignored.

Equation (3.37) is consistent with the physical picture of Kondo lattices that local spin fluctuations interact with each other with an intersite exchange interaction; $I_s(i\omega_l, \mathbf{q})$ is the intersite exchange interaction. The Néel temperature T_N is determined from Eq. (3.37):

$$T_N = \max[T_N(\mathbf{q})], \quad (3.39a)$$

where $T_N(\mathbf{q})$ as a function of $\mathbf{q}$ is defined by

$$[1 - (1/4)I_s(0, \mathbf{q})\tilde{\chi}_s(0)]_{T=T_N(\mathbf{q})} = 0. \quad (3.39b)$$

According to the definition of T_c , if Eq. (3.39) gives T_N , $T_c \geq T_N$; if not, $T_c \geq 0 \text{ K}$.

The reducible and irreducible three-point vertex functions in the spin channel are decomposed into single-site and multisite terms. The single-site terms can be mapped to the local vertex functions of the mapped Anderson model. If they are denoted by $\tilde{\Lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_l; i\omega_l)$ and $\tilde{\lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_l; i\omega_l)$,

$$\tilde{\Lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_l; i\omega_l) = \frac{\tilde{\lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_l; i\omega_l)}{1 - U\tilde{\pi}_s(i\omega_l)}. \quad (3.40)$$

If Eq. (3.36) is used,

$$U\tilde{\lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_l; i\omega_l) = \frac{2}{\tilde{\chi}_s(i\omega_l)}\tilde{\Lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_l; i\omega_l). \quad (3.41)$$

3.2 Perturbation scheme to include multisite terms

3.2.1 Unperturbed state

In the Anderson model of Eq. (3.4), the Fermi surface of the conduction band is defined by $\tilde{\mu} = E_c(\mathbf{k}_F)$, where $\mathbf{k}_F$ is the Fermi wave number. According to Eq. (3.7), $\Delta(0) > 0$ is a sufficient condition for the existence of the Fermi surface. According to Eq. (3.17), the Fermi surface exists. Then, the ground state of the Anderson model is the normal Fermi liquid because of the Kondo effect. The normal Fermi liquid is characterized by nonzero $T_K(T)$, which depends on T of the reservoir for the Hubbard model, or the *parameter* T . For convenience, $\tilde{T}$ of the reservoir for the Anderson model is treated as being independent of the *parameter* T , although eventually $\tilde{T} = T$ has to be assumed. In the following part, we assume that $0 \text{ K} \leq \tilde{T} \lesssim T_K(T)$ and $T_c < T \ll T_K(T)$, and the *parameter* T is explicitly shown.

We introduce an infinitesimal Zeeman energy into the Anderson model: $\tilde{\mathcal{H}}_Z = -\tilde{h}(n_{d\uparrow} - n_{d\downarrow})$, where $\tilde{h} = 0^+$. The self-energy can be expanded in such a way that³⁶⁻³⁸

$$\begin{aligned} \tilde{\Sigma}_\sigma(\varepsilon + i0; T) = & \tilde{\Sigma}_0(T) + [1 - \tilde{\phi}_1(T)]\varepsilon + \sigma[1 - \tilde{\phi}_s(T)]\tilde{h} \\ & - i[\tilde{\phi}_{21}(T)\varepsilon^2 + \tilde{\phi}_{22}(T)(k_B\tilde{T})^2]/[\pi\Delta(0; T)] \\ & - \tilde{\phi}_2(T)\varepsilon^2/[\pi\Delta(0; T)] + \cdots \end{aligned} \quad (3.42)$$

In general, $\tilde{\phi}_1(T) \geq 1$, $\tilde{\phi}_s(T) \geq 1$, $\tilde{\phi}_{21}(T) \geq 0$, $\tilde{\phi}_{22}(T) \geq 0$, and $\tilde{\phi}_2(T) \geq 0$; if $\mu = \mu_0$, $\tilde{\phi}_2(T) = 0$. If $\tilde{U}/[\pi\Delta(0; T)] \gtrsim 1$ and $\tilde{n}(\tilde{\mu}) \simeq 1$, $\tilde{\phi}_1(T) \gg 1$, $\tilde{\phi}_{21}(T) \gg 1$, and $\tilde{\phi}_{22}(T) \gg 1$.

For convenience, we define three ratios:

$$\tilde{W}_s(T) = \tilde{\phi}_s(T)/\tilde{\phi}_1(T), \quad (3.43a)$$

$$\tilde{W}_{21}(T) = \tilde{\phi}_{21}(T)/\tilde{\phi}_1^2(T), \quad (3.43b)$$

$$\tilde{W}_{22}(T) = \tilde{\phi}_{22}(T)/\tilde{\phi}_1^2(T). \quad (3.43c)$$

Any of them is $O(1)$, even if $\tilde{U}/[\pi\Delta(0; T)] \gtrsim 1$. The ratio $\tilde{W}_s(T)$ is nothing but the Wilson ratio.³⁵ If $\Delta(\varepsilon; T)$ does not depend on ε , $\tilde{W}_s(T) = 2$ in the s - d model or the s - d limit of the Anderson model.³⁵⁻³⁷ Thus, it is expected that, if $\tilde{U}/[\pi\Delta(0; T)] \gtrsim 1$ and $\tilde{n}(\tilde{\mu}) \simeq 1$, then $\tilde{W}_s(T) \simeq 2$ for the mapped Anderson model, whose $\Delta(\varepsilon; T)$ depends on ε .

The Fermi-liquid relation is available for the normal Fermi

liquid.^{25,26,36–38} If $\tilde{T} = 0$ K and no polarization of conduction electrons occurs, the static susceptibility of the Anderson model is given by

$$\tilde{\chi}_s(0; T) = 2\tilde{\phi}_s(T)\tilde{\rho}(0; T), \quad (3.44)$$

where $\tilde{\rho}(0; T)$ is the density of states of the Anderson model. If $\Delta(\varepsilon; T)$ depends on ε , the polarization of conduction electrons occurs, in general; the static susceptibility of the Anderson model is approximately given by Eq. (3.44). Since $T_K(T)$ is defined by Eq. (3.34), it follows that

$$1/\tilde{\rho}(0; T) \simeq 2\tilde{\phi}_s(T)k_B T_K(T) \simeq 4\tilde{\phi}_1(T)k_B T_K(T). \quad (3.45)$$

Since an electron liquid in the Hubbard model can be characterized by $\rho_\mu(0; T) = \tilde{\rho}(0; T)$, $\tilde{\phi}_1(T)$, and $k_B T_K(T)$, Eq. (3.45) is useful in the present paper.

The bosonic energy for $\tilde{T}$ is denoted by $\tilde{\omega}_l = 2\pi l k_B \tilde{T}$, with l being an integer. According to the Ward relation,³⁹

$$\tilde{\Lambda}_s(i\tilde{\varepsilon}_l, i\tilde{\varepsilon}_l + i\tilde{\omega}_{l'}; i\tilde{\omega}_{l'}; T) = 1 - \lim_{\hbar \rightarrow 0} \frac{d}{d\hbar} \sum_{\sigma} \frac{\sigma}{2} \tilde{\Sigma}_{\sigma}(i\tilde{\varepsilon}_l; T), \quad (3.46)$$

for $\tilde{\omega}_{l'} = 0$. According to Eqs. (3.42) and (3.46),

$$\tilde{\Lambda}_s(i\tilde{\varepsilon}_l, i\tilde{\varepsilon}_l + i\tilde{\omega}_{l'}; i\tilde{\omega}_{l'}; T) = \tilde{\phi}_s(T), \quad (3.47)$$

for $\tilde{\omega}_{l'} = 0$ and $|\varepsilon_l|/(k_B T_K) \rightarrow 0$. According to Eqs. (3.41) and (3.47),

$$U\tilde{\Lambda}_s(i\tilde{\varepsilon}_l, i\tilde{\varepsilon}_l + i\tilde{\omega}_{l'}; i\tilde{\omega}_{l'}; T) = 2\tilde{\phi}_s(T)/\tilde{\chi}_s(i\tilde{\omega}_{l'}; T), \quad (3.48)$$

for $\tilde{\omega}_{l'} = 0$ and $|\varepsilon_l|/(k_B T_K) \rightarrow 0$.

Every single-site property depends on the *parameter* T . If $T_c < T \ll T_K(T)$, the *parameter* T dependence is so small that it can be ignored, except in the case of $D = 2$ and $n(\mu) \simeq 1$, as discussed in Sect. 5.3. In the following part, $\tilde{T} = T$ is assumed, and the *parameter* T is not shown.

If Eq. (3.42) is used, the Green function is given by

$$G_{\sigma}(i\varepsilon_l, \mathbf{k}) = (1/\tilde{\phi}_1)g_{\sigma}(i\varepsilon_l, \mathbf{k}), \quad (3.49a)$$

$$g_{\sigma}(i\varepsilon_l, \mathbf{k}) = \frac{1}{i\varepsilon_l + \mu^* - [E(\mathbf{k}) + \Delta\Sigma_{\sigma}(i\varepsilon_l, \mathbf{k})]/\tilde{\phi}_1 - \tilde{\gamma}_K(i\varepsilon_l)}, \quad (3.49b)$$

$$\mu^* = (\mu - \tilde{\Sigma}_0)/\tilde{\phi}_1, \quad (3.49c)$$

$$\tilde{\gamma}_K(i\varepsilon_l) = -i \frac{\varepsilon_l}{|\varepsilon_l|} [\tilde{W}_{21}(i\varepsilon_l)^2 + \tilde{W}_{22}(k_B T)^2] \frac{\tilde{\phi}_1}{\pi\Delta(0)}. \quad (3.49d)$$

In Eq. (3.49b), $\tilde{h}$ and $-\tilde{\phi}_2\varepsilon^2/[\pi\Delta(0)]$ are ignored. The Green function given here is accurate for $|\varepsilon_l| \ll k_B T_K$ and $T \ll T_K$; it can be approximately used for $|\varepsilon_l| \lesssim k_B T_K$ and $T \lesssim T_K$ with sufficient accuracy.

If $\tilde{\phi}_1 \gg 1$, the density of states $\tilde{\rho}(\varepsilon)$ of the Anderson model has a three-peak structure with the Kondo peak between two subpeaks; the bandwidth and spectral weight of the Kondo peak are $O(k_B T_K)$ and $1/\tilde{\phi}_1$, respectively.^{36,37} Since $\rho_{\mu}(\varepsilon) = \tilde{\rho}(\varepsilon)$, the density of states $\rho_{\mu}(\varepsilon)$ of the Hubbard model also has a three-peak structure with a midband between the upper and lower Hubbard bands, or within the Hubbard gap that is a pseudogap; the bandwidth and spectral weight of the midband are also $O(k_B T_K)$ and $1/\tilde{\phi}_1$, respectively. In this case, the Green function given by Eq. (3.49) can only describe the midband but the upper or lower Hubbard band.

Equation (3.49b) can also be described as

$$g_{\sigma}(i\varepsilon_l, \mathbf{k}) = g_{\sigma}^{(0)}(i\varepsilon_l, \mathbf{k}) + (1/\tilde{\phi}_1)\Delta\Sigma_{\sigma}(i\varepsilon_l, \mathbf{k})g_{\sigma}(i\varepsilon_l, \mathbf{k}), \quad (3.50)$$

$$g_{\sigma}^{(0)}(i\varepsilon_l, \mathbf{k}) = \frac{1}{i\varepsilon_l + \mu^* - (1/\tilde{\phi}_1)E(\mathbf{k}) - \tilde{\gamma}_K(i\varepsilon_l)}. \quad (3.51)$$

In KLT, $g_{\sigma}^{(0)}(i\varepsilon_l, \mathbf{k})$ is the *unperturbed* Green function, which is determined using the mapped Anderson model; then, the multisite $\Delta\Sigma_{\sigma}(i\varepsilon_l, \mathbf{k})$ of the Hubbard model has to be self-consistently calculated with the mapped Anderson model to satisfy the mapping condition given in Sect. 3.1.1.

3.2.2 Superexchange interaction

We assume that $U/|t| \gg 1$. The intersite $I_s(i\omega_l, \mathbf{q})$ given by Eq. (3.38) can be decomposed into three terms:

$$I_s(i\omega_l, \mathbf{q}) = J_s(i\omega_l, \mathbf{q}) + J_Q(i\omega_l, \mathbf{q}) - \Lambda(i\omega_l, \mathbf{q}). \quad (3.52)$$

Here, $J_s(i\omega_l, \mathbf{q})$ is the superexchange interaction, which arises from the virtual exchange of a pair excitation of an electron in the upper Hubbard band and a hole in the lower Hubbard band,^{32,33} and $J_Q(i\omega_l, \mathbf{q})$ is an exchange interaction due to the virtual exchange of an electron-hole pair excitation within the midband.^{40,41} The last term or $-\Lambda(i\omega_l, \mathbf{q})$ is the sum of all the remaining terms, or the so-called mode-mode coupling term; because it suppresses magnetic instability, it is defined in such a way that the minus sign appears for it.

We refer to previous papers^{32,33} to derive the superexchange interaction. The band splits into the upper and lower Hubbard bands. Since Hubbard's theory is under the single-site approximation (SSA),^{8,9} it can be approximately used to describe the high-energy properties of the Anderson model; the local Green function is given by

$$\tilde{G}_{\sigma}(i\varepsilon_l) = \frac{1}{i\varepsilon_l + \mu - \epsilon_d + \sigma\tilde{h} - \tilde{\Sigma}_{\sigma}(i\varepsilon_l)} \quad (3.53a)$$

$$= \frac{1 - \tilde{n}_{-\sigma}(\mu, \tilde{h})}{i\varepsilon_l + \mu - \epsilon_d} + \frac{\tilde{n}_{-\sigma}(\mu, \tilde{h})}{i\varepsilon_l + \mu - \epsilon_d - U}, \quad (3.53b)$$

for $|\varepsilon_l| \gg k_B T_K$, where $\tilde{n}_{\sigma}(\mu, \tilde{h})$ is the number of localized electrons with spin σ in the presence of the infinitesimal Zeeman energy $\tilde{h}$; in Eq. (3.53b), $\tilde{h}$'s in the denominators are ignored because they are not crucial. It follows that

$$\tilde{\chi}_s(0) = \lim_{\hbar \rightarrow 0} \frac{d}{d\hbar} [\tilde{n}_{\uparrow}(\mu, \tilde{h}) - \tilde{n}_{\downarrow}(\mu, \tilde{h})]. \quad (3.54)$$

According to Eqs. (3.41), (3.46), (3.53), and (3.54),

$$U\tilde{\Lambda}_s(i\varepsilon_l, i\varepsilon_l + i\omega_{l'}; i\omega_{l'}) = -\frac{1}{\tilde{G}_{\sigma}^2(i\varepsilon_l)} \times \left(\frac{1}{i\varepsilon_l + \mu - \epsilon_d} + \frac{1}{i\varepsilon_l + \mu - \epsilon_d - U} \right), \quad (3.55)$$

for $\omega_{l'} = 0$ and $|\varepsilon_l| \gg k_B T_K$.

Since the superexchange interaction is a second-order effect in $-t/\sqrt{D}$, according to Eq. (3.38),

$$J_s(i\omega_l, \mathbf{q}) = \frac{1}{L} \sum_{\langle ij \rangle} e^{i\mathbf{q} \cdot (\mathbf{R}_i - \mathbf{R}_j)} J_{\langle ij \rangle}(i\omega_l), \quad (3.56)$$

$$J_{\langle ij \rangle}(i\omega_l) = 2k_B T \sum_{l'} U^2 \tilde{\lambda}_s^2(i\varepsilon_{l'}, i\varepsilon_{l'} + i\omega_l; i\omega_l) \left(-t/\sqrt{D}\right)^2 \times R_{i\sigma}^2(i\varepsilon_{l'}) R_{j\sigma}^2(i\varepsilon_{l'} + i\omega_l). \quad (3.57)$$

If Eq. (3.53) is used for $R_{i\sigma}(i\varepsilon_l)$ and Eq. (3.55) is used for $U\tilde{\lambda}_s(i\varepsilon_{l'}, i\varepsilon_{l'} + i\omega_l; i\omega_l)$, its static part between nearest neighbors is given by $J_{\langle ij \rangle}(0) = J/D$, where

$$J = -4t^2/U. \quad (3.58)$$

This is simply given in previous papers^{32,33} and is in agreement with that derived from the conventional theory.⁴²

Since $J_{\langle ij \rangle}(\omega + i0)$ is analytical in the upper-half complex plane, $J_{\langle ij \rangle}(i\omega_l)$ can be generally described as

$$J_{\langle ij \rangle}(i\omega_l) = \frac{J}{D} \int_0^{+\infty} dx X_J(x) \left(\frac{1}{i\omega_l + x} - \frac{1}{i\omega_l - x} \right), \quad (3.59)$$

where $X_J(x)$ satisfies

$$\int_0^{+\infty} dx \frac{X_J(x)}{x} = \frac{1}{2}. \quad (3.60)$$

Since $X_J(x)$ has a peak at $x \simeq U$, it is assumed that $X_J(x) = (1/2)U\delta(x - U)$. Then,

$$J_s(i\omega_l, \mathbf{q}) = \frac{2J}{\sqrt{D}} \varphi_D(\mathbf{q}) \frac{U}{2} \left(\frac{1}{i\omega_l + U} - \frac{1}{i\omega_l - U} \right), \quad (3.61)$$

where $\varphi_D(\mathbf{q})$ is defined by Eq. (2.3). In the static limit $|\omega_l|/U \rightarrow 0$, Eq. (3.61) is reduced to

$$J_s(i\omega_l, \mathbf{q}) = \frac{2J}{\sqrt{D}} \varphi_D(\mathbf{q}) = \frac{2J}{D} \sum_{\nu=1}^D \cos(q_\nu a). \quad (3.62)$$

The superexchange interaction $J_s(i\omega_l, \mathbf{q})$ is of higher order in $1/D$ for almost all $\mathbf{q}$'s and is of the zeroth order in $1/D$ only for particular $\mathbf{q}$'s, e.g., $\mathbf{q}$'s on the line between $(\pi/a)(0, \pm 1, \dots, \pm 1)$ and $(\pi/a)(\pm 1, \pm 1, \dots, \pm 1)$.

3.2.3 Mutual interaction due to spin fluctuations

The mutual interaction due to spin fluctuations is given by

$$\Gamma_{\text{sf}}(i\omega_l, \mathbf{q}; i\varepsilon_{l_1}, i\varepsilon_{l_2}) = U^2 \tilde{\lambda}_s(i\varepsilon_{l_1}, i\varepsilon_{l_1} + i\omega_l; i\omega_l) \times \tilde{\lambda}_s(i\varepsilon_{l_2}, i\varepsilon_{l_2} - i\omega_l; -i\omega_l) \times [\chi_s(i\omega_l, \mathbf{q}) - \tilde{\chi}_s(i\omega_l)], \quad (3.63)$$

where $i\varepsilon_{l_1}$ and $i\varepsilon_{l_2}$ are the energies of incoming electrons, $i\varepsilon_{l_1} + i\omega_l$ and $i\varepsilon_{l_2} - i\omega_l$ are those of outgoing electrons, and $i\omega_l$ is the transfer energy. Since the single-site part is considered in the *unperturbed* state, it is subtracted in Eq. (3.63) in order to avoid double counting. It follows that^{33,40,41}

$$\chi_s(i\omega_l, \mathbf{q}) - \tilde{\chi}_s(i\omega_l) = (1/4)\tilde{\chi}^2(i\omega_l)I_s^*(i\omega_l, \mathbf{q}), \quad (3.64)$$

$$I_s^*(i\omega_l, \mathbf{q}) = \frac{I_s(i\omega_l, \mathbf{q})}{1 - (1/4)I_s(i\omega_l, \mathbf{q})\tilde{\chi}_s(i\omega_l)}. \quad (3.65)$$

If Eq. (3.48) is used, it follows that

$$\Gamma_{\text{sf}}(i\omega_l, \mathbf{q}; i\varepsilon_{l_1}, i\varepsilon_{l_2}) = \tilde{\phi}_s^2 I_s^*(i\omega_l, \mathbf{q}), \quad (3.66)$$

for $|\omega_l| \lesssim k_B T_K$, $|\varepsilon_{l_1}| \lesssim k_B T_K$, and $|\varepsilon_{l_2}| \lesssim k_B T_K$. The single-site $\tilde{\phi}_s$ appears as a type of three-point vertex function.

If the mapped Anderson model is solved and the single-site $\tilde{\Sigma}_\sigma(i\varepsilon_l)$ and $\tilde{\chi}_s(i\omega_l)$ are given, the multisite $\Delta\Sigma_\sigma(i\varepsilon_l, \mathbf{k})$ and $\Delta\pi(i\omega_l, \mathbf{q})$ can be perturbatively calculated in terms of the

intersite $I_s(i\omega_l, \mathbf{q})$ on the basis of KLT. Since the single-site terms are considered in the Anderson model, only multisite terms have to be considered in order to avoid double counting. The intersite $I_s(i\omega_l, \mathbf{q})$ has to be treated as a *bare* intersite exchange interaction, and the single-site $\tilde{\phi}_s$ has to be treated as a *bare* vertex function; $I_s^*(i\omega_l, \mathbf{q})$ is the renormalized intersite exchange interaction, which is enhanced or screened by intersite spin fluctuations, depending on $\mathbf{q}$.

The intersite $I_s(i\omega_l, \mathbf{q})$ is of higher order in $1/D$ for almost all $\mathbf{q}$'s except for particular $\mathbf{q}$'s; e.g., $I_s(0, \mathbf{Q})$, where $\mathbf{Q}$ is the ordering wave number determined using Eq. (3.39), is of the zeroth order in $1/D$ and corresponds to the conventional Weiss mean field. Thus, KLT is a perturbative theory in terms of $I_s(i\omega_l, \mathbf{q})$ and also a $1/D$ expansion theory.

4. RVB Liquid in Low Dimensions

4.1 RVB self-energy

We assume that

$$U/|t| \gg 1, \quad |n(\mu) - 1| \ll 1, \quad T_c < T \ll |J|/(k_B D). \quad (4.1)$$

We consider only the superexchange interaction $J_s(i\omega_l, \mathbf{q})$ in the intersite $I_s(i\omega_l, \mathbf{q})$. There are two types of self-energy of the first order in $J_s(i\omega_l, \mathbf{q})$: the Hartree-type and Fock-type self-energies. Since the Hartree-type self-energy is included in the conventional Hartree term, which is one of the single-site terms and is considered in the *unperturbed* state, it should not be considered in order to avoid double counting. The Fock-type self-energy is given by⁴³

$$\Delta\Sigma_\sigma^{(\text{RVB})}(i\varepsilon_l, \mathbf{k}) = \frac{k_B T}{L} \sum_{l' \mathbf{p} \sigma'} \tilde{\phi}_s^2 \frac{1}{4} J_s(i\varepsilon_l - i\varepsilon_{l'}, \mathbf{k} - \mathbf{p}) \times (\boldsymbol{\sigma}^{\sigma\sigma'} \cdot \boldsymbol{\sigma}'^{\sigma'\sigma}) G_{\sigma'}(i\varepsilon_{l'}, \mathbf{p}), \quad (4.2)$$

where $\boldsymbol{\sigma} = (\sigma_x, \sigma_y, \sigma_z)$ is the Pauli matrix. What is considered for the Fock-type self-energy is simply the RVB mechanism.⁴⁴ We call it the RVB self-energy.

If Eqs. (3.49) and (3.61) are used, it follows that

$$\Delta\Sigma_\sigma^{(\text{RVB})}(i\varepsilon_l, \mathbf{k}) = \tilde{\phi}_1 \frac{3}{4} \tilde{W}_s^2 \frac{J}{D} \Xi_D(i\varepsilon_l) \varphi_D(\mathbf{k}), \quad (4.3)$$

where $\tilde{W}_s$ is the Wilson ratio, $J = -4t^2/U$, and

$$\Xi_D(i\varepsilon_l) = \frac{1}{L} \sum_{\mathbf{p}} \varphi_D(\mathbf{p}) \left\{ \frac{1}{2} U \left[f_-(U) g_\sigma(i\varepsilon_l + U, \mathbf{p}) - f_-(-U) g_\sigma(i\varepsilon_l - U, \mathbf{p}) \right] - \frac{1}{\pi} \int_{-\infty}^{+\infty} d\epsilon f_+(\epsilon) \frac{1}{2} U \left(\frac{1}{i\varepsilon_l - \epsilon + U} - \frac{1}{i\varepsilon_l - \epsilon - U} \right) \times \text{Im} g_\sigma(\epsilon + i0, \mathbf{p}) \right\}, \quad (4.4)$$

where $g_\sigma(\epsilon + i0, \mathbf{p})$ is given by Eq. (3.49b) and

$$f_\pm(\epsilon) = 1/[e^{\epsilon/(k_B T)} \pm 1]. \quad (4.5)$$

It is easy to confirm that

$$\lim_{|\varepsilon_l|/U \rightarrow +\infty} \Delta\Sigma_\sigma^{(\text{RVB})}(i\varepsilon_l, \mathbf{k}) = 0, \quad (4.6)$$

which is crucial to prove the sum rule in Appendix A. In the

static limit $|\varepsilon_l|/U \rightarrow 0$, $\Xi_D(i\varepsilon_l)$ is simply given by

$$\Xi_D = \frac{1}{L} \sum_{\mathbf{p}} \varphi_D(\mathbf{p}) \int_{-\infty}^{+\infty} d\epsilon f_+(\epsilon) \left(-\frac{1}{\pi} \right) \text{Im} g_\sigma(\epsilon + i0, \mathbf{p}). \quad (4.7)$$

If $|\varepsilon_l|/U \ll 1$, Eq. (4.7) can be used for $\Xi_D(i\varepsilon_l)$ with sufficient accuracy. Then,

$$\Delta \Sigma_\sigma^{(\text{RVB})}(i\varepsilon_l, \mathbf{k}) = \tilde{\phi}_1 \frac{3}{4} \tilde{W}_s^2 \frac{J}{D} \Xi_D \varphi_D(\mathbf{k}). \quad (4.8)$$

If Eq. (3.62) is used instead of Eq. (3.61), Eq. (4.8) is simply derived instead of Eq. (4.3).

4.2 Parameters characterizing the RVB liquid

If Eq. (4.8) is used, Eq. (3.49b) is simply given by

$$g_\sigma(i\varepsilon_l, \mathbf{k}) = \frac{1}{i\varepsilon_l + \mu^* - \xi(\mathbf{k}) - \tilde{\gamma}_K(i\varepsilon_l)}, \quad (4.9)$$

where μ^* and $\tilde{\gamma}_K(i\varepsilon_l)$ are given by Eqs. (3.49c) and (3.49d), respectively,

$$\xi(\mathbf{k}) = -2t^* \varphi_D(\mathbf{k}), \quad (4.10)$$

$$t^* = t \left[(1/\tilde{\phi}_1) + 2c_J |t|/(DU) \right], \quad (4.11)$$

$$c_J = (3/4) \tilde{W}_s^2 \Xi_D. \quad (4.12)$$

The density of states at the chemical potential is given by

$$\rho_\mu(0) = -\frac{1}{\pi L} \sum_{\mathbf{k}} \frac{1}{\tilde{\phi}_1} \text{Im} g_\sigma(+i0, \mathbf{k}) = O\left(\frac{1}{\tilde{\phi}_1 |t^*|}\right). \quad (4.13)$$

From Eqs. (3.45) and (4.13), it follows that

$$k_B T_K = O(|t^*|). \quad (4.14)$$

Electrons in the midband can be described by μ^* , t^* or $k_B T_K$, $\tilde{\phi}_1$, and c_J . In principle, they have to be self-consistently evaluated with each other as a function of T and μ to satisfy the mapping condition given in Sect. 3.1.1. However, they can be approximately evaluated, as studied below.

According to the Fermi-surface sum rule,^{25,26}

$$n(\mu) = \frac{2}{L} \sum_{\mathbf{k}} \int_{-\infty}^{+\infty} d\epsilon f_+(\epsilon) \delta[\epsilon + \mu^* - \xi(\mathbf{k})], \quad (4.15)$$

for $T = 0$ K. If $T = 0$ K and $n(\mu) = 1$, then $\mu^* = 0$, which is required by the particle-hole symmetry. Then, $|\Xi_1| = 1/\pi = 0.31831 \dots$, $|\Xi_2| = 2\sqrt{2}/\pi^2 = 0.28658 \dots$, and $|\Xi_\infty| = 1/(2\sqrt{\pi}) = 0.283095 \dots$; i.e., $|\Xi_D| \simeq 1/3$ for any D . If $T_c < T \ll T_K$, Eq. (4.15) can be approximately used, but with sufficient accuracy. If $n(\mu) \simeq 1$, it follows that

$$|\mu^*| \ll |t^*|, \quad |\Xi_D| \simeq 1/3, \quad c_J \simeq 1. \quad (4.16)$$

If $|\Xi_D| = 1/3$ and $\tilde{W}_s = 2$ are assumed, then $c_J = 1$.

The asymptotic behavior of $1/\tilde{\phi}_1$ as $U/|t| \rightarrow +\infty$ is studied in Appendix B: If $n(\mu) = 1$, $1/\tilde{\phi}_1 = O[t^2/(DU^2)]$, as shown in Eq. (B-11). According to Gutzwiller's theory,⁴⁵⁻⁴⁷ if $U/|t| \rightarrow +\infty$ and $|n(\mu) - 1| \ll 1$, $1/\tilde{\phi}_1 = O(|n(\mu) - 1|)$. If $U/|t| \gg 1$ and $|n(\mu) - 1| \ll 1$, it is reasonable to assume that

$$1/\tilde{\phi}_1 = \max\{O[t^2/(DU^2)], O[|n(\mu) - 1|]\}. \quad (4.17)$$

4.3 Possible types of electron liquid

If Eq. (4.1) is satisfied, the spectral weight of the midband, which is $1/\tilde{\phi}_1$, is much smaller than unity, and the bandwidth

of the midband, which is $O(|t|^*)$, is much smaller than the bare bandwidth, which is $O(|t|)$. We consider four typical cases of Eq. (4.1), where $t^2/(DU^2) \ll |t|/(DU)$. First, we consider the case of

$$t^2/(DU^2) \ll |t|/(DU) \lesssim |n(\mu) - 1|, \quad (4.18)$$

where $n(\mu) \neq 1$ is assumed. According to Eq. (4.18) together with Eqs. (4.11), (4.13), (4.14), and (4.17),

$$1/\tilde{\phi}_1 = O(|n(\mu) - 1|), \quad (4.19a)$$

$$\rho_\mu(0) = O(1/|t|), \quad (4.19b)$$

$$k_B T_K = O[|t| \cdot |n(\mu) - 1|]. \quad (4.19c)$$

The single-site effect considered by Gutzwiller's theory is more crucial than the RVB mechanism; $\rho_\mu(0)$ weakly increases as U increase. If $|t|/(DU) \ll |n(\mu) - 1|$, the electron liquid is simply that given by Gutzwiller's theory,⁴⁵⁻⁴⁷ which is under SSA. If $n(\mu)$ is kept constant, $\rho_\mu(0)$ is constant as a function of U under SSA, as will be discussed later in Sect. 5.1; thus, $\rho_\mu(0)$ for such a large U is almost constant as a function of U and as large as that for $U = 0$.

Second, we consider the case of

$$t^2/(DU^2) \lesssim |n(\mu) - 1| \lesssim |t|/(DU), \quad (4.20)$$

where $n(\mu) \neq 1$ is also assumed; U in this case is smaller than that considered in the first case, if $n(\mu) \neq 1$ are the same as each other between the two cases. It follows that

$$1/\tilde{\phi}_1 = O(|n(\mu) - 1|), \quad (4.21a)$$

$$O(1/U) < \rho_\mu(0) < O(1/|t|), \quad (4.21b)$$

$$k_B T_K = O[t^2/(DU)] = O(|J|/D). \quad (4.21c)$$

The RVB mechanism is crucial and the electron liquid is the RVB liquid. Since the single-site effect becomes more and more relatively crucial to the RVB mechanism as U increases, $\rho_\mu(0)$ increases as U increases.

Third, we consider the case of

$$|n(\mu) - 1| \lesssim t^2/(DU^2) \ll |t|/(DU), \quad (4.22)$$

where $n(\mu) \neq 1$ or $n(\mu) = 1$ is assumed; if $n(\mu) \neq 1$ are the same as each other between this case and the first or second case, U in this case is smaller than that considered in the first or second case. It follows that

$$1/\tilde{\phi}_1 = O[t^2/(DU^2)], \quad (4.23a)$$

$$\rho_\mu(0) = O(1/U), \quad (4.23b)$$

$$k_B T_K = O[t^2/(DU)] = O(|J|/D). \quad (4.23c)$$

The RVB mechanism is crucial and the electron liquid is a typical type of RVB liquid. The density of states $\rho_\mu(0)$ becomes smaller as U increases. Particularly if $n(\mu) = 1$, $\rho_\mu(0) \rightarrow 0$ as $U/|t| \rightarrow +\infty$. According to Eq. (3.12),

$$\Delta(\varepsilon) = -|\text{Im} \Sigma_\sigma(\varepsilon + i0)| + 1/[\pi \rho_\mu(\varepsilon)], \quad (4.24)$$

for ε such that $\text{Re} R_\sigma(\varepsilon + i0) = 0$. Since $\text{Re} R_\sigma(+i0) = 0$ for $\mu = \mu_0$ and $\text{Im} \Sigma_\sigma(+i0) \rightarrow 0$ as $T \rightarrow 0$ K, $\Delta(0) = O(U)$.

According to the considerations of the above three cases, the RVB mechanism is crucial, provided that

$$|n(\mu) - 1| \lesssim |t|/(DU). \quad (4.25)$$

If $n(\mu) \neq 1$ is kept constant, $\rho_\mu(0)$ is not a monotonous function of U ; $\rho_\mu(0)$ as a function of U is minimal at approximately U such that $|n(\mu) - 1| = t^2/(DU^2)$. If $n(\mu) = 1$, $\rho_\mu(0)$ is a monotonously decreasing function of U : $\rho_\mu(0) \propto 1/U$.

Last, we consider a particular case of Eq. (4.22): the Heisenberg limit of $U/|t| \rightarrow +\infty$ with $J = -4t^2/U$ and $n(\mu) = 1$ kept constant. It follows that $1/\tilde{\phi}_1 \rightarrow 0$, $\rho_\mu(0) \rightarrow 0$, and $k_B T_K = O(|J|/D)$. Although the bandwidth of the mid-band is nonzero and finite, either its spectral weight or density of states is infinitesimal. The RVB electron liquid in the Heisenberg limit is the most typical type of RVB electron liquid; it is a quasi-spin liquid, or simply the RVB spin liquid.

4.4 Metallic conductivity in the Heisenberg limit

We consider magnetic impurities:

$$\mathcal{H}' = - \sum_{i\sigma\sigma'} J'_i \left(\boldsymbol{\sigma}^{\sigma\sigma'} \cdot \mathbf{S}'_i \right) d_{i\sigma}^\dagger d_{i\sigma'}, \quad (4.26)$$

where $\mathbf{S}'_i$ is an impurity spin at the i th unit cell. We consider an ensemble for J'_i such that J'_i is positive, zero, or negative and is completely random from unit cell to unit cell and from sample to sample in the ensemble: $\langle\langle J'_i \rangle\rangle = 0$, $\langle\langle J'_i J'_j \rangle\rangle = \delta_{ij} \langle\langle |J'_i|^2 \rangle\rangle$, $\langle\langle J'_{i_1} J'_{i_2} J'_{i_3} \rangle\rangle = 0$, and so on, where $\langle\langle \dots \rangle\rangle$ stands for the ensemble average. The translational symmetry is restored by the ensemble average. In the following part, the double thermal-ensemble average is simply called an *average*.

Assuming that $|J'_i| \ll k_B T_K$ for any i , we treat impurity scattering in the Born approximation. The *average* self-energy $\bar{\Sigma}_\sigma(i\varepsilon_l)$ due to the impurity scattering is given by self-consistently solving the following two equations:

$$\bar{\Sigma}_\sigma(i\varepsilon_l) = \tilde{\phi}_s^2 S'(S' + 1) \delta_{ij} \langle\langle |J'_i|^2 \rangle\rangle \frac{1}{L} \sum_{\mathbf{k}} \frac{1}{\tilde{\phi}_1} \bar{g}_\sigma(i\varepsilon_l, \mathbf{k}), \quad (4.27)$$

$$\bar{g}_\sigma(i\varepsilon_l, \mathbf{k}) = \frac{1}{i\varepsilon_l + \mu^* - \xi(\mathbf{k}) - \tilde{\gamma}_K(i\varepsilon_l) - (1/\tilde{\phi}_1) \bar{\Sigma}_\sigma(i\varepsilon_l)}, \quad (4.28)$$

where S' is the magnitude of impurity spins, $\bar{g}_\sigma(i\varepsilon_l, \mathbf{k})$ is the *average* Green function multiplied by $\tilde{\phi}_1$, which corresponds to $g_\sigma(i\varepsilon_l, \mathbf{k})$ given by Eq. (3.49b) or (4.9), and $\tilde{\gamma}_K(i\varepsilon_l)$ is given by Eq. (3.49d). The *average* conductivity is given by⁴⁸

$$\sigma_{xx}(\omega) = \frac{\hbar}{i\omega} \left[K_{xx}(\omega + i0) - K_{xx}(0) \right], \quad (4.29)$$

where

$$\begin{aligned} K_{xx}(i\omega_l) &= \frac{1}{La^D} \int_0^\beta d\tau e^{i\omega_l \tau} \left\langle e^{\tau(\mathcal{H} - \mu\mathcal{N})} \hat{j}_x e^{-\tau(\mathcal{H} - \mu\mathcal{N})} \hat{j}_x \right\rangle \\ &= \frac{e^2}{\hbar^2} \frac{(2t)^2}{Da^{D-2}} \Pi_{xx}(i\omega_l), \end{aligned} \quad (4.30)$$

where $\beta = 1/(k_B T)$, $\hat{j}_x = -(e/\hbar) \sum_{\mathbf{k}\sigma} [(\partial/\partial k_1) E(\mathbf{k})] \hat{n}_{\mathbf{k}}$, with $\hat{n}_{\mathbf{k}\sigma} = (1/L) \sum_{ii'} e^{i\mathbf{k} \cdot (\mathbf{R}_i - \mathbf{R}_{i'})} d_{i\sigma}^\dagger d_{i'\sigma}$, and

$$\begin{aligned} \Pi_{xx}(i\omega_l) &= \frac{1}{L} \sum_{\mathbf{k}\mathbf{p}} \sum_{\sigma\sigma'} \sin(k_1 a) \sin(p_1 a) \int_0^\beta d\tau e^{i\omega_l \tau} \\ &\quad \times \left\langle e^{\tau(\mathcal{H} - \mu\mathcal{N})} \hat{n}_{\mathbf{k}\sigma} e^{-\tau(\mathcal{H} - \mu\mathcal{N})} \hat{n}_{\mathbf{p}\sigma'} \right\rangle. \end{aligned} \quad (4.31)$$

Here, $\langle \dots \rangle$ stands for the *average*. In order to satisfy the Ward relation,³⁹ the ladder type of vertex correction due to the su-

perexchange interaction has to be considered; the vertex correction due to the impurity scattering to be considered is also of the ladder type, but it vanishes. Then,

$$\Pi_{xx}(i\omega_l) = \frac{1}{\tilde{\phi}_1^2} \frac{2\pi_{xx}(i\omega_l)}{1 + 3\tilde{W}_s^2 J \pi_{xx}(i\omega_l)/(4D)}, \quad (4.32)$$

where $\tilde{W}_s$ is the Wilson ratio and

$$\pi_{xx}(i\omega_l) = -\frac{k_B T}{L} \sum_{n\mathbf{k}} \sin^2(k_x a) \bar{g}_\sigma(i\varepsilon_l, \mathbf{k}) \bar{g}_\sigma(i\varepsilon_l + i\omega_l, \mathbf{k}). \quad (4.33)$$

The ω -linear term of $K_{xx}(\omega + i0)$ or $\Pi_{xx}(\omega + i0)$ contributes to the static conductivity $\sigma_{xx}(0)$. It follows that

$$\frac{d\Pi_{xx}(i\omega_l)}{d(i\omega_l)} = \frac{(2/\tilde{\phi}_1^2) [d\pi_{xx}(i\omega_l)/d(i\omega_l)]}{[1 + 3\tilde{W}_s^2 J \pi_{xx}(i\omega_l)/(4D)]^2}. \quad (4.34)$$

If Eq. (C-6) is used, it is easy to show that

$$[1 + 3\tilde{W}_s^2 J \pi_{xx}(0)/(4D)] \tilde{\phi}_1 t^* = t, \quad (4.35)$$

with t^* given by Eq. (4.11). Then, it follows that

$$\sigma_{xx}(0) = \frac{e^2}{\hbar^2} \frac{(2t^*)^2}{Da^{D-2}} S_{xx}(0), \quad (4.36)$$

where $S_{xx}(0) = (2\hbar/i) [(d/d\omega) \pi_{xx}(\omega + i0)]_{\omega=0}$, or

$$S_{xx}(0) = \frac{2\hbar}{\pi L} \sum_{\mathbf{k}} \sin^2(k_1 a) \int_{-\infty}^{+\infty} d\varepsilon \left[-\frac{f_+(\varepsilon)}{d\varepsilon} \right] \left[\text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k}) \right]^2. \quad (4.37)$$

If $2 \sin^2(k_1 a) = 1 - \cos(2k_1 a)$ is used and the term that includes $\cos(2k_1 a)$ is ignored, it follows that

$$\begin{aligned} S_{xx}(0) &= \frac{\hbar}{\pi} \int_{-\infty}^{+\infty} dE \left[\tilde{\phi}_1 \rho_\mu(E) \right] \int_{-\infty}^{+\infty} d\varepsilon \left[-\frac{f_+(\varepsilon)}{d\varepsilon} \right] \\ &\quad \times \left[\text{Im} \frac{1}{\varepsilon - E - \tilde{\gamma}_K(\varepsilon + i0) - (1/\tilde{\phi}_1) \bar{\Sigma}_\sigma(\varepsilon + i0)} \right]^2. \end{aligned} \quad (4.38)$$

We define two relaxation times, τ_K and τ_s , by

$$\begin{aligned} \frac{\hbar}{2\tau_K} &= \int_{-\infty}^{+\infty} d\varepsilon \left[-\frac{df_+(\varepsilon)}{d\varepsilon} \right] \text{Im} [-\tilde{\gamma}_K(\varepsilon + i0)] \\ &= \left(\frac{\pi^2}{3} \tilde{W}_{21} + \tilde{W}_{22} \right) \frac{\tilde{\phi}_1}{\pi \Delta(0)} (k_B T)^2, \end{aligned} \quad (4.39)$$

$$\frac{\hbar}{2\tau_s} = \int_{-\infty}^{+\infty} d\varepsilon \left[-\frac{df_+(\varepsilon)}{d\varepsilon} \right] \frac{1}{\tilde{\phi}_1} \text{Im} [-\bar{\Sigma}_\sigma(\varepsilon + i0)], \quad (4.40)$$

respectively. If $-i\hbar/(2\tau_K)$ and $-i\hbar/(2\tau_s)$ are used for $\tilde{\gamma}_K(\varepsilon + i0)$ and $(1/\tilde{\phi}_1) \bar{\Sigma}_\sigma(\varepsilon + i0)$, respectively, and the energy dependence of $\rho_\mu(E)$ is ignored in Eq. (4.38), it follows that

$$\sigma_{xx}(0) = \frac{e^2}{\hbar^2} \frac{8|t^*|^2}{Da^{D-2}} \frac{\tilde{\phi}_1 \rho_\mu(0)}{(1/\tau_K) + (1/\tau_s)}. \quad (4.41)$$

Since $|t^*| = O(|J|/D)$ and $\tilde{\phi}_1 \rho_\mu(0) = O(1/|t^*|)$, $\sigma_{xx}(0)$ is nonzero even in the limit $1/\tilde{\phi}_1 \rightarrow 0$; $\rho_\mu(0) \rightarrow 0$ in the limit $1/\tilde{\phi}_1 \rightarrow 0$. In an *absolutely* clean system, $\hbar/\tau_s = 0$. If no symmetry is broken or no complete gap opens even at $T = +0$ K in the *absolutely* clean system, $\sigma_{xx}(0)$ diverges as $T \rightarrow 0$ K because $1/\tau_K \rightarrow 0$ as $T \rightarrow 0$ K. If the impurity scattering is sufficiently weak, the RVB electron liquid shows metallic conduc-

tivity at a sufficiently low T such that $k_B T_c < k_B T \ll |J|/D$ in not only three dimensions or higher but also, if the Anderson localization⁴⁹ can be ignored, one and two dimensions, and even in the Heisenberg limit, in which $\rho_\mu(0) \rightarrow 0$.

4.5 Adiabatic continuation

In the Heisenberg limit, the Hubbard model is reduced to

$$\mathcal{H}_S = L\epsilon_d - \frac{1}{2} \frac{J}{D} \sum_{\langle ij \rangle} (\mathbf{S}_i \cdot \mathbf{S}_j) - 2 \sum_i J'_i (\mathbf{S}_i \cdot \mathbf{S}'_i), \quad (4.42)$$

where the Hilbert space is constrained within the subspace where no empty or double occupancy is allowed, and $\mathbf{S}_i = (1/2) \sum_{\sigma\sigma'} \boldsymbol{\sigma}^{\sigma\sigma'} d_{i\sigma}^\dagger d_{i\sigma'}$. The last term in Eq. (4.42) is the impurity term given by Eq. (4.26). Since $\mathbf{S}_i$'s satisfy the commutation relation for spin within the constrained Hilbert subspace, if the impurity term is excluded, $\mathcal{H}_S$ is the Heisenberg model. The local gauge symmetry does not exist in the Hubbard model but exists in the Heisenberg model: $[\mathcal{H}, n_{i\uparrow} + n_{i\downarrow}] \neq 0$ and $[\mathcal{H}_S, n_{i\uparrow} + n_{i\downarrow}] = 0$ for any i .

The role of the superexchange interaction is dual: the cause and suppression of magnetic instability. Since no suppression occurs in infinite dimensions, the mean-field approximation is rigorous for the Heisenberg model in infinite dimensions; the Néel temperature is as high as $T_N = |J|/(2k_B)$ in not only the Heisenberg model but also the Heisenberg limit of the Hubbard model, as will be shown later in Eq. (5.15). The Néel temperature T_N is suppressed by two mechanisms: critical spin fluctuations and the RVB mechanism.¹ The RVB mechanism stabilizes or prefers an unordered electron liquid in the Hubbard model and an unordered spin liquid in the Heisenberg model, rather than the Néel state. The stabilization energy due to the RVB mechanism is $O(|J|/D)$ per pair of nearest neighbors or per unit cell; the RVB mechanism is $O(1/D)$. If D is sufficiently small such that no T_N exists or, if it exists, $T_N \ll |J|/(Dk_B)$, electron and spin liquids in the Hubbard and Heisenberg models at T such that $T_N < T \ll |J|/(Dk_B)$ are the RVB electron and spin liquids, respectively.

The local gauge symmetry is a peculiar symmetry such that it cannot be spontaneously broken nor restored.⁵⁰ In the reduction of the Hubbard model into the Heisenberg model, the local gauge symmetry is *not spontaneously* restored but is *forced* to be restored by constraining the Hilbert space within the subspace. The difference in the local gauge symmetry between two phases can never deny the possibility of the adiabatic continuation between them, as discussed below.

The relationship between the Hubbard and Heisenberg models is similar to that between the Anderson and s - d models. In the s - d limit, the Anderson model is reduced to the s - d model. The local gauge symmetry does not exist in the Anderson model but exists in the s - d model. The density of states for d electrons can be defined in the Anderson model. If it is denoted by $\tilde{\rho}(\varepsilon)$, $\tilde{\rho}(\varepsilon) > 0$ at least for a sufficiently small ε , which means that low-energy single-particle excitations are possible, as in the Hubbard model. On the other hand, $\tilde{\rho}(\varepsilon)$ cannot be defined in the s - d model, which means that no single-particle excitation is possible, as in the Heisenberg model. On the other hand, according to Nozières' theory,⁵¹ it is possible to describe the spin liquid in the s - d model as the normal Fermi liquid. The Fermi-liquid theory for the spin liquid in the s - d model is exactly equivalent to that for

the Fermi liquid in the Anderson model in the s - d limit.^{36,37} Thus, the spin liquid in the s - d model adiabatically continues to the Fermi liquid in the Anderson model.

The conductivity of the RVB spin liquid is zero, but that of the RVB electron liquid can be divergent at $T = +0$ K even in the Heisenberg limit if no impurity exists and no symmetry is broken even at $T = +0$ K, as studied in Sect. 4.4. This extreme difference in the conductivity cannot exclude the possibility of the adiabatic continuation between the RVB spin and electron liquids either, as discussed below.

The strength of magnetic impurities can be used as an adiabatic parameter. Here, it is assumed that $-\infty < J'_i < +\infty$ and $0 < \langle |J'_i|^2 \rangle < +\infty$. Clean and dirty limits are defined by the limit $\langle |J'_i|^2 \rangle \rightarrow 0$ and the limit $\langle |J'_i|^2 \rangle \rightarrow +\infty$, respectively. In the dirty-limit Hubbard model, an electron is localized almost within a unit cell, so that the local gauge symmetry is almost *restored* and the conductivity is almost zero. It is certain that every physical property of the dirty-limit Hubbard model in the Heisenberg limit is the same as that of the dirty-limit Heisenberg model. Thus, the electron state in the dirty-limit Hubbard model in the Heisenberg limit and the spin state in the dirty-limit Heisenberg model adiabatically continue to each other.

According to the scaling theory for the Anderson localization,⁴⁹ there is no critical point between the metallic and insulating phases, or between the itinerant and localized states, or between the clean and dirty limits; there is also no lower limit of the metallic conductivity or minimum metallic conductivity. Therefore, the RVB electron liquid in the clean-limit Hubbard model adiabatically continues to the electron state in the dirty-limit Hubbard model. It is obvious that the RVB spin liquid in the clean-limit Heisenberg model adiabatically continues to the spin state in the dirty-limit Heisenberg model. Thus, the RVB electron liquid in the clean-limit Hubbard model and the RVB spin liquid in the clean-limit Heisenberg model adiabatically continue to each other.

5. Discussion

5.1 Nature of the Mott insulator

Either the Mott insulator or Lieb and Wu's insulator competes with the RVB liquid. It is desirable to examine its nature in order to confirm that the RVB liquid is stable against it. Here, we examine the nature of the Mott insulator. We assume that $U/|t| \gg 1$ and $\mu = \mu_0$, unless otherwise noted.

If $T > T_c$, no symmetry is broken. The Kondo energy $k_B T_K$ is the energy scale of quantum spin fluctuations in the RVB liquid as well as a measure of its stabilization energy: $k_B T_K = O[t^2/(DU)]$.⁵² We assume that D is so small that $T_c \ll T_K$. If T is so low that $T_c < T \ll T_K$, quantum spin fluctuations are more dominant than thermal spin fluctuations, the entropy is small, and electrons are itinerant. The RVB liquid is stabilized in the low- T phase of $T_c < T \ll T_K$ in sufficiently low dimensions. If T is so high that $T \gg T_K$, thermal spin fluctuations are more dominant than quantum spin fluctuations, the entropy is as large as $k_B \ln 2$ per unit cell, and electrons behave as local moments. Since the high- T phase where $T \gg T_K$ behaves as an insulator, it is simply the Mott insulator. An MI transition or crossover occurs at $T \simeq T_K$ as a function of T between the RVB liquid and the Mott insulator. Then, a high- T phase where $T \gtrsim T_K$, rather than $T \gg T_K$, is

also the Mott insulator. If D is so large that $T_c \gtrsim T_K$, a high- T phase where $T > T_c$ is the Mott insulator because $T \gtrsim T_K$. The Mott insulator is stabilized as a high- T phase with a large entropy in low or high dimensions, while the RVB liquid is stabilized as a low- T phase with a small entropy only in sufficiently low dimensions. The Mott insulator and the RVB liquid never contradict each other.

If $T \leq T_c$, the symmetry is broken, except for one dimension. If $T_c \gtrsim T_K$, not only the Néel state but also the type of insulator proposed by Slater⁵³ is possible below T_c in a multi-band model, as will be discussed later in Sect. 5.5.

Since the RVB mechanism is a multisite effect, it never appears under S^3A ; it is expected that $k_B T_K = 0$ will be possible for $U/|t| \gg 1$. Since any type of the conventional Weiss mean field is also a multisite effect, it never appears under S^3A ; no symmetry can be broken. It is expected that the Mott insulator, which is a high- T phase with a large entropy, will be possible even at $T = 0$ K under S^3A .

According to a numerical study²⁹ based on DMFT or S^3A , the Mott insulator is possible even at $T = 0$ K. An MI transition with hysteresis occurs below the critical temperature T_0 . The hysteresis is characterized by two transition lines of $U_{c1}(T)$ and $U_{c2}(T)$ in the T - U phase diagram. The model used in the numerical study is different from that used in the present study. If the absolute bandwidth is denoted by W , $U_{c1}(T) \simeq W$, $U_{c2}(T) \simeq W$, and $U_{c1}(T) < U_{c2}(T)$ for $T < T_0$; $U_{c1}(T_0) = U_{c2}(T_0)$. When U increases, an MI transition occurs at $U = U_{c2}(T)$; when U decreases, it occurs at $U = U_{c1}(T)$. The insulating phase at $T = 0$ K for $U \geq U_{c1}(0$ K) or $U \geq U_{c2}(0$ K), depending on the decreasing or increasing process of U , is a typical type of the Mott insulator, i.e., *the Mott insulator in which a complete gap opens*.

According to our previous paper,¹³ either under or beyond S^3A , a complete gap opens if and only if $\tilde{\Sigma}_\sigma(\varepsilon + i0)$ and/or $\tilde{\Gamma}(\varepsilon + i0)$ of the Anderson model has a pole at $\varepsilon = 0$; when $\mu = \mu_0$, e.g., a gap as large as ϵ_0 opens if and only if

$$\tilde{\Sigma}_\sigma(\varepsilon + i0) = \frac{U}{2} + \frac{|\lambda_\Sigma|}{\varepsilon + i0} - \frac{1}{\pi} \left[\int_{-\infty}^{-\epsilon_0/2} d\epsilon + \int_{+\epsilon_0/2}^{+\infty} d\epsilon \right] \frac{\text{Im} \tilde{\Sigma}_\sigma(\epsilon + i0)}{\varepsilon - \epsilon + i0}, \quad (5.1a)$$

$$\tilde{\Gamma}(\varepsilon + i0) = \frac{|\lambda_\Gamma|}{\varepsilon + i0} - \frac{1}{\pi} \left[\int_{-\infty}^{-\epsilon_0/2} d\epsilon + \int_{+\epsilon_0/2}^{+\infty} d\epsilon \right] \frac{\text{Im} \tilde{\Gamma}(\epsilon + i0)}{\varepsilon - \epsilon + i0}, \quad (5.1b)$$

with $|\lambda_\Sigma| > 0$ or $|\lambda_\Gamma| > 0$, are satisfied. If $|\lambda_\Sigma| > 0$, or if $\tilde{\Sigma}_\sigma(\varepsilon + i0)$ has a pole at $\varepsilon = 0$, $k_B T_K = 0$ and the residual entropy of the Hubbard model is $k_B \ln 2$ per unit cell. If $\lambda_\Sigma = 0$ and $|\lambda_\Gamma| > 0$, or if only $\tilde{\Gamma}(\varepsilon + i0)$ has a pole at $\varepsilon = 0$, the residual entropy is zero; the argument in our previous paper¹³ that if $|\lambda_\Gamma| > 0$ then $|\lambda_\Sigma|$ has to be nonzero is irrelevant.

Since $\tilde{\Gamma}(\varepsilon + i0)$ can have no pole at $\varepsilon = 0$ under S^3A ,¹³ $\tilde{\Sigma}_\sigma(\varepsilon + i0)$ has to have a pole at $\varepsilon = 0$ for the Mott insulator at $T = 0$ K. Then, $k_B T_K = 0$ and the residual entropy is $k_B \ln 2$ per unit cell, i.e., the third law of thermodynamics is broken. The Mott insulator at $T = 0$ K has to be regarded as a high- T phase rather than a low- T phase. Either under or beyond S^3A , the Mott insulator can be stabilized only as a high- T phase with a large entropy but can never be stabilized as a low- T phase with a small entropy, even if it is stabilized at $T = 0$ K.

If symmetry breaking is ignored, it is easy to extend the analysis based on KLT to $T \leq T_c$, except for $T = 0$ K. If

$T > 0$ K, $\rho_\mu(\varepsilon) > 0$ even if the ground state is an insulator. Then, $k_B T_K = O[t^2/(DU)]$. If $T \gtrsim T_K$, the Mott insulator is stabilized; if $0 < T \ll T_K$, the RVB liquid is stabilized. An MI transition or crossover occurs at $T \simeq T_K$ as a function of T between them. The analysis for $T > 0$ K never denies the possibility that $\rho_\mu(0) = 0$ for $T = 0$ K, i.e., the ground state is an insulator.⁵⁴

Since no higher-order term in $1/D$ is included in S^3A , strictly speaking, it is not a theory for $1/D \rightarrow 0$ but a theory for exactly $1/D = 0$. It should be determined whether, if symmetry breaking is ignored, S^3A is equivalent to KLT in the limit $1/D \rightarrow 0$ and rigorous in the limit $1/D \rightarrow 0$.

Beyond S^3A , or in KLT, $k_B T_K = O[t^2/(DU)]$ is more or less nonzero. In the limit of $1/D \rightarrow 0$ followed by $T \rightarrow 0$ K, $T \gg T_K$ and the Mott insulator is stabilized; the numerical study²⁹ based on DMFT or S^3A is consistent with KLT. In the limit of $T \rightarrow 0$ K followed by $1/D \rightarrow 0$, $T \ll T_K$ and the RVB liquid is stabilized; the numerical study is inconsistent with KLT. The inconsistency means or implies that S^3A is not rigorous in the limit $1/D \rightarrow 0$.

In the limit $U/|t| \rightarrow 0$, if T is so low that $k_B T \ll |t|$, a metal is stabilized, because $k_B T_K = O(|t|)$ and $T \ll T_K$. In the limit $U/|t| \rightarrow +\infty$, if T is nonzero, the Mott insulator is stabilized, because $k_B T_K = O[t^2/(DU)] \rightarrow 0$ as $U/|t| \rightarrow +\infty$ and $T \gg T_K$. If T is nonzero and sufficiently low such that $0 < k_B T \ll |t|$, an MI crossover or transition occurs as a function of U . Since $k_B T_K = O[t^2/(DU)]$ is nonzero for any $|t|/U > 0$ unless $1/D = 0$, it is expected that no transition but only a crossover will occur beyond S^3A . If this expectation is true, the transition in the numerical study²⁹ is inconsistent with the crossover beyond S^3A . Against the expectation, we assume that a transition is possible at a sufficiently low T beyond S^3A . We consider the model used in the numerical study; its absolute bandwidth, which is finite, is also denoted by W , as in the discussion above. The Kondo energy is given by $k_B T_K = O[W^2/(DU)]$ in the limit $T \rightarrow 0$ K. Since no transition is possible as a function of T at least in the limit $U/W \rightarrow 0$, a critical point has to exist in the T - U phase diagram. If hysteresis exists, $U_{c1}(+0 \text{ K}) < U_{c2}(+0 \text{ K})$; if not, $U_{c1}(+0 \text{ K}) = U_{c2}(+0 \text{ K})$. Since $k_B T_K = O[W^2/(DU)]$ is more or less nonzero for any $W/U > 0$ unless $1/D = 0$, $U_{c2}(T) \rightarrow +\infty$ as $T \rightarrow 0$ K for any finite D ; i.e., at least $U_{c2}(+0 \text{ K})$ is infinite beyond S^3A , regardless of whether hysteresis exists or not. In the numerical study, on the other hand, hysteresis appears and either $U_{c1}(0 \text{ K})$ or $U_{c2}(0 \text{ K})$ is finite and $O(W)$,⁵⁵ as discussed above. The finite $U_{c2}(0 \text{ K})$ or $U_{c2}(+0 \text{ K})$ in the numerical study is inconsistent with the infinite $U_{c2}(+0 \text{ K})$ beyond S^3A . The T - U phase diagram of the numerical study is inconsistent with that beyond S^3A , regardless of whether an MI crossover or transition occurs beyond S^3A . This finding also means or implies that S^3A is not rigorous even in the limit $1/D \rightarrow 0$.

We consider an electron state in the limit $T \rightarrow 0$ K, never at $T = 0$ K. If $k_B T_K > 0$, the electron state is a metal. Thus, $\text{Im} \Sigma_\sigma(+i0, \mathbf{k}) \rightarrow 0$ as $T \rightarrow 0$ K. Then,

$$\rho_\mu(0) = \frac{1}{L} \sum_{\mathbf{k}} \delta[\mu - E(\mathbf{k}) - \text{Re} \Sigma_\sigma(+i0, \mathbf{k})], \quad (5.2a)$$

and, according to the Fermi-surface sum rule,^{25,26}

$$n(\mu) = \frac{1}{L} \sum_{\mathbf{k}\sigma} \theta[\mu - E(\mathbf{k}) - \text{Re}\Sigma_\sigma(+i0, \mathbf{k})], \quad (5.2b)$$

where $\theta(x) = (1 + x/|x|)/2$. Under S³A or SSA, the self-energy $\Sigma_\sigma(+i0, \mathbf{k})$ does not depend on $\mathbf{k}$. It is easy to show that $\rho_\mu(0)$ is constant as a function of U if $n(\mu)$ is kept constant; $\rho_\mu(0)$ is simply given by that for $U = 0$. The constant $\rho_\mu(0)$ as a function of U is a property peculiar to the metallic phase under SSA. If the Mott transition occurs, the decrease in $\rho_\mu(0)$ with increasing U is necessarily discontinuous from the constant $\rho_\mu(0)$ of the metal to the zero $\rho_\mu(0)$ of the Mott insulator. On the other hand, if the RVB mechanism is considered and if Eq. (B·11) or $1/\tilde{\phi}_1 = O[t^2/(DU)]$ is used, $\Delta\Sigma_\sigma^{(\text{RVB})}(+i0, \mathbf{k}) \propto (1/D)^0 U \varphi_D(\mathbf{k})$.⁵⁶ If $U/|t| \gg 1$, the dispersion of $E(\mathbf{k})$ can be ignored in Eq. (5.2). Then, $\rho_\mu(0) = O(1/U)$ for $\mu = \mu_0$ or $n(\mu) = 1$. The continuous decrease in $\rho_\mu(0)$ with increasing U is a property peculiar to the RVB liquid with the half filling. The inconsistency in the U dependence of $\rho_\mu(0)$ between under and beyond S³A also means or implies that S³A is not rigorous even in the limit $1/D \rightarrow 0$.

Any of the three inconsistencies discussed above between the numerical study²⁹ and the present paper is simply because the RVB mechanism cannot be considered under S³A but can be considered beyond S³A. Beyond S³A, $k_B T_K = O[t^2/(DU)]$ is nonzero. If the Mott insulator in which a completely opens, which is characterized by $k_B T_K = 0$, is possible at $T = 0$ K under S³A, S³A is not necessarily equivalent to KLT in the limit $1/D \rightarrow 0$ nor necessarily rigorous in the limit $1/D \rightarrow 0$. The rigorousness of S³A in the limit $1/D \rightarrow 0$ is examined in Appendix D.

5.2 Nature of Lieb and Wu's insulator

If the fact that $\rho_\mu(0) > 0$ for $T > 0$ K is seriously considered, the RVB-TL liquid is stabilized in the low- T phase of $0 \text{ K} < T \ll |J|/k_B$ in one dimension; the possibility is not denied that $\rho_\mu(0) = 0$ for $T = 0$ K, i.e., the ground state is an insulator.⁵⁴ According to the treatment in Sect. 2.2.2, the ground state for $|\mu - \mu_0| < (1/2)\epsilon_G(U)$ in the grand canonical ensemble is simply Lieb and Wu's insulator itself, which is given by the Bethe-ansatz solution for the canonical ensemble. Here, we examine the nature of this insulator. We assume that $D=1$, $T=0$ K, and $U/|t| \gg 1$, unless otherwise noted.

If the Bethe-ansatz solution is used, it is possible to determine all the physical properties in the grand canonical ensemble with essentially the same treatment as that in Sect. 2.2.2, in principle; then, it is also possible to determine the mapped Anderson model, in principle. We assume that the Anderson model is determined and solved. Since a complete gap opens in Lieb and Wu's insulator and its residual entropy per unit cell is zero or infinitesimal in the thermodynamic limit, the scenario that $\lambda_\Sigma = 0$ and $|\lambda_\Gamma| > 0$ in Eq. (5.1) is only possible for the insulator: $\tilde{\Sigma}_\sigma(\varepsilon + i0)$ is analytic at $\varepsilon = 0$, but $\tilde{\Gamma}(\varepsilon + i0)$ has a pole at $\varepsilon = 0$, or just on μ . If the insulator is *rigid* against the movement of μ , as discussed in Sect. 2.2.2, the pole of $\tilde{\Gamma}(\varepsilon + i0)$ moves as μ moves. If $\mu \neq \mu_0$, $\tilde{\Gamma}(\varepsilon + i0)$ has a pole at $\varepsilon \neq 0$ on the real axis. Since $\Delta(\varepsilon) = -\text{Im}\tilde{\Gamma}(\varepsilon + i0)$, as shown in Eq. (3.7), $\Delta(\varepsilon) = 0$ for $\varepsilon \simeq 0$. If so, there is no Fermi surface in the Anderson model, so that the ground state of the Anderson

model is not the normal Fermi liquid and $\tilde{\Sigma}_\sigma(\varepsilon + i0)$ is not analytic at $\varepsilon = 0$. There is inconsistency between the possibility and *rigidity* of Lieb and Wu's insulator.

Three explanations are possible for this inconsistency: One is the pinning of the chemical potential, as in Wilson's insulator. If not only the long-range Coulomb interaction but also the formation of an electric double layer between Wilson's insulator and its reservoir is considered, the gap center is pinned to the chemical potential of the reservoir. If a similar or different type of pinning is possible between Lieb and Wu's insulator and its reservoir, it is possible that the band center ϵ_d is adjusted in such a way that the gap center $\mu_0 = \epsilon_d + (1/2)U$ is pinned to the chemical potential of the reservoir. However, it seems plausible that there is no appropriate pinning mechanism in one dimension. Another is that Lieb and Wu's insulator is so singular that it cannot be treated by KLT. Either the gap function or the ground-state energy is singular at $U = 0$ as a function of U .^{6,11} This means that Lieb and Wu's insulator cannot be treated by a simple perturbation in terms of U . If the gap-opening or Eq. (5.1) is assumed from the beginning,²⁷ KLT may treat Lieb and Wu's insulator for $\mu = \mu_0$; however, KLT can never treat Lieb and Wu's insulator for $\mu \neq \mu_0$. In other words, the Bethe-ansatz solution for Lieb and Wu's insulator may be a self-consistent solution of KLT for $\mu = \mu_0$ but can never for $\mu \neq \mu_0$. This finding means or implies that Lieb and Wu's insulator is unstable or impossible in the grand canonical ensemble, at least for $\mu \neq \mu_0$. Then, the most probable explanation is that the ground state for $|\mu - \mu_0| < (1/2)\epsilon_G(U)$ is not Lieb and Wu's insulator itself, which is an eigenstate of $\mathcal{N}$, but an electron state that is no eigenstate of $\mathcal{N}$, a type of insulator different from Lieb and Wu's insulator or simply the RVB-TL electron liquid in the limit $T \rightarrow 0$ K. Not only an excited state but also the ground state has to be *nonrigid* against the movement of μ in the grand canonical ensemble, except for Wilson's band insulator; the ground state can be *nonrigid* at least if it is more or less a linear combination or mixture of different N states, e.g., because of an electron reservoir.

We assume the *explicit* presence of an electron reservoir in $D \geq 1$ dimensions. A many-body eigenstate is no eigenstate of $\mathcal{N}$. We define the *efficiency* of the reservoir by⁵⁷

$$\delta N = \sqrt{\langle (\mathcal{N} - \langle \mathcal{N} \rangle)^2 \rangle}. \quad (5.3)$$

It is plausible that $\delta N \gg 1$ and $\delta N/L \rightarrow 0$ as $L \rightarrow +\infty$, if the reservoir is appropriate. If more or less $\delta N > 0$, $\langle \mathcal{N} \rangle$ can be not only an integer but also an irrational number; $\langle \mathcal{N} \rangle$ is continuous as a function of μ . If no symmetry breaking occurs, it is likely that the nature of electron correlation is continuous as a function of the continuous variable $\langle \mathcal{N} \rangle$; then, it is unlikely that there exists a critical deviation δN_c from the half filling such that the ground state is an insulator for $|\langle \mathcal{N} \rangle - L| < \delta N_c$ but is a metal for $|\langle \mathcal{N} \rangle - L| > \delta N_c$. This argument implies that neither Lieb and Wu's insulator nor the Mott insulator in which a complete gap opens is possible.

In our previous paper,²¹ the reservoir effect is considered with a simple model in $D \geq 1$ dimensions in which the translational symmetry is restored by the ensemble average. If symmetry breaking is ignored, the Green function is given by

$$G_\sigma(i\varepsilon_l, \mathbf{k}) = \frac{1}{i\varepsilon_l + \mu - E(\mathbf{k}) - \Sigma_\sigma(i\varepsilon_l, \mathbf{k}) - \Gamma_R(i\varepsilon_l)}, \quad (5.4)$$

where $\Gamma_R(i\epsilon_l)$ is due to hybridization with the reservoir. From the mapping condition, it follows that²¹

$$\Delta(\epsilon) \geq -\text{Im}\Gamma_R(\epsilon + i0). \quad (5.5)$$

If the reservoir is appropriate, $-\text{Im}\Gamma_R(\epsilon + i0) = +0^+$. Since $\Delta(\epsilon)$ is nonzero, $k_B T_K$ has to be more or less nonzero and the single-site $\tilde{\Sigma}_\sigma(\epsilon + i0)$ has to be more or less normal. If $\Delta(0) < +\infty$ is assumed, it is easy to extend the analysis in Sect. 4 to this model, regardless of T . If $|n(\mu) - 1| \lesssim |t|/(DU)$, e.g., the ground state is the RVB liquid with $k_B T_K = O(|J|/D)$, $\rho_\mu(0) = O(1/U)$, and $\Delta(0) = O(U)$; the eventual $\Delta(0)$ is consistent with the assumption of $\Delta(0) < +\infty$. The liquid is not *rigid* against the movement of μ ; e.g., the three-peak structure with the midband between the Hubbard bands varies with μ . Since $\Delta(\epsilon) > 0$ for $T = 0$ K is no assumption, it is definite that the Mott insulator at $T = 0$ K in which a complete gap opens is impossible. It is reasonable that the Mott insulator at $T = 0$ K is unstable even against the infinitesimal $\Gamma_R(\epsilon + i0)$, because it is infinitely degenerate. Since $\Delta(0) < +\infty$ or $\tilde{\Gamma}(\epsilon + i0)$ with no pole at $\epsilon = 0$ for $T = 0$ K is assumed, the possibility cannot be denied that an MI transition occurs at $T = 0$ K and the ground state is an insulator in which the third law of thermodynamics holds. The insulator, if possible, has to be a mixture of different N states and cannot be Lieb and Wu's insulator itself, which is an eigenstate of $\mathcal{N}$; it is desirable to determine the critical δN_c defined above and the critical μ corresponding to N_c/L in order to confirm that either the transition or insulator at $T = 0$ K is actually possible, although either is of no physical significance.⁵⁴

If the reservoir is appropriate, the modification of many-body eigenstates of the Bethe-ansatz solution by the reservoir has to be small. It is, therefore, expected that

$$n[\mu_0 \pm (1/2)\epsilon_G(U)] = 1 \pm O(\delta N/L), \quad (5.6a)$$

$$[\chi_c(0,0)]_{|\mu-\mu_0| < (1/2)\epsilon_G(U)} = O[(\delta N/L)/\epsilon_G(U)], \quad (5.6b)$$

regardless of the ground state. If $\delta N > 0$ once, metallic configurations with $N \neq L$ contribute to any statistical average in the grand canonical ensemble. It is expected that more or less $\rho_\mu(0) > 0$ regardless of T . If so, it is easy to extend the analysis for $T > 0$ K in Sect. 4 to $T = 0$ K. The ground state is the RVB-TL liquid even for $|\mu - \mu_0| < (1/2)\epsilon_G(U)$; it has to be simply that in the limit $T \rightarrow 0$ K. If Eq. (5.6) is satisfied, many physical properties of the liquid cannot depend on μ : e.g., $n(\mu) = 1$, $\chi_c(0,0) = 0$,⁵⁸ $k_B T_K = O(|J|/D)$, $\rho_\mu(0) = O(1/U)$, and so on. Few properties can depend on μ : e.g., the three peak structure with the midband between the Hubbard bands. The liquid is not *rigid* against the movement of μ . It is expected that the physical properties of the liquid will be the same as those of Lieb and Wu's insulator, expect for those closely related to the itineracy of electrons. On the other hand, the possibility cannot be denied that $\rho_\mu(0) = 0$ even for $\delta N > 0$. In this case, the ground state is a type of insulator different from Lieb and Wu's insulator, because it cannot be *rigid* against the movement of μ . It is desirable to determine which is the ground state for $|\mu - \mu_0| < (1/2)\epsilon_G(U)$ in the grand canonical ensemble, Lieb and Wu's insulator, a type of insulator different from it, or the RVB-TL liquid,⁵⁴ particularly in the *explicit* presence of a realistic and appropriate electron reservoir, in which there is no translational symmetry, $\delta N \gg 1$, and $\delta N/L \rightarrow 0$ as $L \rightarrow +\infty$.

5.3 RVB liquid in low dimensions

If $U/|t| \gg 1$ in sufficiently low- D dimensions, $T_c \ll |J|/(k_B D)$ can be satisfied. The low- T phase of $T_c < T \ll |J|/(k_B D)$ is mainly studied in the present paper. Since $\rho_\mu(0)$ of this phase is necessarily more or less nonzero, there is no doubt that KLT can treat the phase, even if KLT cannot treat Lieb and Wu's insulator itself. If $|n(\mu) - 1| \lesssim |t|/(DU)$, the RVB liquid is stabilized in the low- T phase.

First, we consider one dimension, for which $T_c = 0$ K. The RVB liquid in one dimension is also the RVB-TL liquid. The *intermediate* phase with $|\mu - \mu_0| \leq (1/2)\epsilon_G(U)$ is also simply the RVB-TL liquid. Since Eq. (5.6) has to be satisfied in the limit $T \rightarrow 0$ K, $n(\mu) \rightarrow 1$ and $\chi_c(0,0) \rightarrow 0$ as $T \rightarrow 0$ K for the *intermediate* phase; $n(\mu) \simeq 1$ and $\chi_c(0,0) \simeq 0$ for the phase at $T > 0$ K. On the other hand, if $|\mu - \mu_0| > (1/2)\epsilon_G(U)$, $\chi_c(0,0)$ is nonzero regardless of T . It is expected that a metal-metal (MM) transition or crossover will occur at $\mu \simeq \mu_0 \pm (1/2)\epsilon_G(U)$ as a function of μ between the RVB-TL liquid with nonzero $\chi_c(0,0)$ and the *intermediate* phase with zero or small $\chi_c(0,0)$; if an MM crossover occurs, the crossover has to be very sharp at a sufficiently low T and almost a transition in the limit $T \rightarrow 0$ K. It is also expected that the conductivity of the *intermediate* phase will be metallic or of a *bad* metal due to $2k_F$ and $4k_F$ fluctuations peculiar to one dimension but never of an activation type whose activation energy is $O[\epsilon_G(U)]$. It is expected that the physical properties of the *intermediate* phase will be almost the same as those of Lieb and Wu's insulator in the canonical ensemble, except for those closely related to the itineracy of electrons.

We consider the Heisenberg limit at $T = +0$ K. If only the RVB self-energy is considered beyond S³A, the spectrum of a single-particle excitation of the RVB-TL liquid is given by

$$\xi(k) = c_J J \cos(ka) - \mu^*, \quad (5.7)$$

where $c_J \simeq 1$ and $\mu^* = 0$. The spectrum of an electron-hole pair excitation is given by

$$\begin{aligned} \omega(q) &= \xi(k+q) - \xi(k) \\ &= c_J |J| \{ \cos[(k+q)a] - \cos(ka) \}, \end{aligned} \quad (5.8)$$

where $\cos[(k+q)a] > 0$ and $\cos(ka) < 0$. Then,

$$c_J |J \sin(qa)| \leq \omega(q) \leq 2c_J |J \sin(qa/2)|. \quad (5.9)$$

In the Heisenberg limit, low-energy charge fluctuations are almost completely depressed; thus, the pair excitation $\omega(q)$ is almost a spin excitation. The *spin-excitation* spectrum $\omega(q)$ in the Hubbard model is similar to the spin-excitation spectrum in the Heisenberg model.⁵⁹ The similarity of the *spin-excitation* spectrum is evidence of the adiabatic continuation between the RVB-TL electron and spin liquids.

According to previous papers,⁶⁰⁻⁶² the spin liquid in the Heisenberg model is the TL spin liquid; i.e., it is the RVB-TL spin liquid. This is also evidence of the adiabatic continuation between the RVB-TL electron and spin liquids.

The ground-state energy of Lieb and Wu's insulator as a function of a complex $z = t/U$ has no singularity at $z = 0$.¹¹ This fact means or implies that Lieb and Wu's insulator adiabatically continues to the RVB-TL spin liquid; if so, the insulator also adiabatically continues to the RVB-TL electron liquid. It is certain that the RVB mechanism is also crucial for the stabilization of Lieb and Wu's insulator. The RVB-TL

electron liquid in the *intermediate* phase in the grand canonical ensemble and Lieb and Wu's insulator in the canonical ensemble are never contradictory to each other. The similarity and difference between them have to be similar to those between the RVB-TL electron and spin liquids.

Next, we consider two dimensions. The Hubbard model on the square lattice is also of particular interest; no symmetry can be broken at $T > 0$ K,⁵ $\rho_\mu(\varepsilon)$ for $U = 0$ diverges logarithmically as $\varepsilon \rightarrow 0$ because of the saddle-point van Hove singularity peculiar to two dimensions, and the Fermi surface for $U = 0$ shows a perfect nesting for $\mathbf{q} = \mathbf{Q}$, where $\mathbf{Q} = (\pm 1, \pm 1)(\pi/a)$, in the half-filled case. We assume that $U/|t| \gg 1$ and $\mu = \mu_0$.

The static susceptibility of the Anderson model is approximately given by Eq. (3.44): $\tilde{\chi}_s(0; T) \simeq 4\tilde{\phi}_1\rho_\mu(0)$. If T is nonzero, the logarithmic divergence of $\tilde{\phi}_1\rho_\mu(\varepsilon)$ as $\varepsilon \rightarrow 0$ is suppressed by the imaginary part of the self-energy. Since the suppression disappears in the limit $T \rightarrow 0$ K, it is expected that $\tilde{\chi}_s(0; T) \rightarrow +\infty$ as $T \rightarrow 0$ K.⁶³ The Fermi surface shows a sharp nesting for $\mathbf{Q}$, at least for $0 \text{ K} < T \ll |J|/(2k_B)$. The superexchange interaction $J_s(0, \mathbf{q})$ is maximum at $\mathbf{q} = \mathbf{Q}$. Thus, the half-filled ground state is presumably the Néel state with the ordering vector $\mathbf{Q}$. The low- T phase of $0 \text{ K} < T \ll |J|/(2k_B)$ is the RVB electron liquid in the critical region.

We consider the T dependence of the static homogeneous susceptibility; it can be described as

$$1/\chi_s(0, 0; T) = 1/\chi_s(0, \mathbf{Q}; T) + (1/4)[\Delta_s + \Delta_Q(T) - \Delta_\Gamma(T)], \quad (5.10)$$

$$\Delta_s = J_s(0, \mathbf{Q}) - J_s(0, 0) = 4|J|, \quad (5.11)$$

$$\Delta_Q(T) = J_Q(0, \mathbf{Q}; T) - J_Q(0, 0; T), \quad (5.12)$$

$$\Delta_\Gamma(T) = \Lambda_\Gamma(0, \mathbf{Q}; T) - \Lambda_\Gamma(0, 0; T), \quad (5.13)$$

from Eq. (3.37). The T dependence of Δ_s can be ignored. It is expected that an anomaly will appear in $\chi_s(0, 0; T)$ of the RVB liquid in the critical region, as discussed below.

As preliminary, we consider D dimensions. According to previous papers,^{33,40} if μ lies in the vicinity of one of the band edges and $\rho_\mu(\varepsilon)$ has a sharp peak in the vicinity of μ , $J_Q(0, \mathbf{q}; T)$ is ferromagnetic; i.e., $J_Q(0, 0; T)$ is positively large and $J_Q(0, 0; T)$ increases almost linearly against T as $T \rightarrow 0$ K. On the other hand, if μ lies around the band center and the Fermi surface shows a sharp nesting, it is antiferromagnetic; i.e., $J_Q(0, \mathbf{Q}_N; T)$ is positively large and $J_Q(0, \mathbf{Q}_N; T)$ increases almost linearly against T as $T \rightarrow 0$ K, where $\mathbf{Q}_N$ is the nesting wave number. The T dependence of $J_Q(0, \mathbf{q}; T)$ is a mechanism of the Curie-Weiss (CW) law, as will be discussed later in Sect. 5.4.

We consider two dimensions. The Fermi surface shows a sharp nesting for $\mathbf{Q} = (\pm 1, \pm 1)(\pi/a)$, so that $J_Q(0, \mathbf{Q}; T)$ is positively large at $T \ll |J|/(2k_B)$ and $J_Q(0, \mathbf{Q}; T)$ increases as $T \rightarrow 0$ K. The density of states $\rho_\mu(\varepsilon)$ has a logarithmic peak at the band center, so that $J_Q(0, 0; T)$ is also positive at $T \ll |J|/(2k_B)$ and $J_Q(0, 0; T)$ increases as $T \rightarrow 0$ K. Since both μ and the peak of $\rho_\mu(\varepsilon)$ are at the band center, the nesting effect is larger than the logarithmic-peak effect. Then, $\Delta_Q(T) > 0$ and the T dependence of $J_Q(0, \mathbf{Q}; T)$ is much stronger than that of $J_Q(0, 0; T)$. The T dependence of $\Delta_Q(T)$ is large; $\Delta_Q(T)$ increases as $T \rightarrow 0$ K. The Néel

temperature T_N cannot be nonzero because of critical fluctuations, or $\Lambda(0, \mathbf{q}; T)$; this means that the T dependence of $\Lambda(0, \mathbf{q}; T)$ is large. In general, the $\mathbf{q}$ dependence of the mode-mode coupling term $\Lambda(0, \mathbf{q}; T)$ is small. Then, $\Delta_\Gamma(T)$ has to be small and the T dependence of the small $\Delta_\Gamma(T)$ is also small. In the critical region, the CW law is suppressed by $\Lambda(0, \mathbf{q}; T)$, and $\chi_s(0, \mathbf{Q}; T)$ is almost constant as a function of T . Thus, according to Eq. (5.10), the T dependence of $1/\chi_s(0, 0; T)$ resembles that of $\Delta_Q(T)$. Since $\Delta_Q(T)$ increases as $T \rightarrow 0$ K, $1/\chi_s(0, 0; T)$ increases as $T \rightarrow 0$ K, i.e., $\chi_s(0, 0; T)$ decreases as $T \rightarrow 0$ K. The decrease in or suppression of $\chi_s(0, 0; T)$ as $T \rightarrow 0$ K also occurs in the Heisenberg model on the square lattice.^{64,65} This similarity of the suppression of $\chi_s(0, 0; T)$ is evidence of the adiabatic continuation between the RVB electron and spin liquids.

It is easy to extend the study in the present paper to a different type of Hubbard model, i.e., one on a different symmetry or type of lattice and/or with not only t between nearest neighbors but also t' , t'' , and so on between other neighbors. The superexchange interaction appears between not only nearest neighbors but also other neighbors: $J \propto |t|^2/U$, $J' \propto |t'|^2/U$, $J'' \propto |t''|^2/U$, and so on. Since the RVB mechanism is of the first order in the superexchange interaction, the eventual stabilization energy or $k_B T_K$ is the sum of the contributions of J , J' , J'' , and so on. Since $k_B T_K$ is nonzero for a finite D , the same qualitative conclusion as that for the Hubbard model of Eq. (2.1) can be drawn for a different type of Hubbard model.

The most interesting extension is that to the triangular lattice. If $T > 0$ K, no symmetry is broken.⁵ The electron state at $0 \text{ K} < T \ll |J|/(Dk_B)$ in the Hubbard model is a frustrated electron liquid, and the spin state at $0 \text{ K} < T \ll |J|/(Dk_B)$ in the Heisenberg model is the RVB spin liquid proposed by Fazekas and Anderson.¹ We propose that the frustrated electron liquid in the Hubbard model is simply the RVB electron liquid, and that the RVB electron and spin liquids in the Hubbard and Heisenberg models on the triangular lattice adiabatically continue to each other.

In three dimensions and higher, it is possible that $T_N \ll |J|/(Dk_B)$, at least, if frustration or quasi-low dimensionality is sufficient in the Hubbard and Heisenberg models. If $T_N \ll |J|/(Dk_B)$, it is interesting to study how magnetic properties at $T_N < T \ll |J|/(Dk_B)$ resemble each other between an electron liquid in the Hubbard model in the strong-coupling region, which is the RVB electron liquid, and a spin liquid in the Heisenberg model, which is the RVB spin liquid.

5.4 Itinerant electrons versus local moments

Electrons behave as local moments at $T \gg T_K$, or local moments form at $T \gg T_K$. We consider the half-filled case in infinite dimensions or in the limit $1/D \rightarrow 0$ as the most typical case. Assuming that $T > T_N$, where T_N is the Néel temperature to be determined, we consider $\chi_s(0, \mathbf{q})$ given by Eq. (3.37) with $I_s(0, \mathbf{q})$ given by Eq. (3.52). As $1/D \rightarrow 0$, $k_B T_K = O(|J|/D) \rightarrow 0$ and $\Lambda(0, \mathbf{q}) \rightarrow 0$, because they are of higher order in $1/D$. Since $T/T_K \rightarrow +\infty$, $J_Q(0, \mathbf{q}) \rightarrow 0$ and $\tilde{\chi}_s(0) = 1/(k_B T)$. Then,

$$\chi_s(0, \mathbf{q}) = 1/[k_B T - (1/4)J_s(0, \mathbf{q})], \quad (5.14)$$

$$T_N = J_s(0, \mathbf{Q})/(4k_B) = |J|/(2k_B), \quad (5.15)$$

where $\mathbf{Q} = (\pm 1, \pm 1, \dots, \pm 1)(\pi/a)$. The static susceptibility $\chi_s(0, \mathbf{q})$ obeys the CW law of local-moment magnetism due to the T dependence of the single-site $\tilde{\chi}_s(0)$. Both $\chi_s(0, \mathbf{q})$ and T_N are in agreement with those in the mean-field approximation for the Heisenberg model. These agreements are reasonable because either the $1/D$ expansion theory or the mean-field approximation is rigorous in the limit $1/D \rightarrow 0$.

If $T > T_N$ and $T \gg T_K$, $\chi_s(0, \mathbf{q})$ is approximately given by Eq. (5.14) even for a finite D . If $T \gg T_K$, local moments form in either low or high dimensions.

The Kondo energy $k_B T_K$ is also the energy scale of quantum spin fluctuations. If $T \ll T_K$, the ensemble of electrons or spins behaves as a liquid, i.e., an electron or spin liquid. If $T \gg T_K$, electrons or spins behave as local moments. Itinerant-electron magnetism and local-moment magnetism are characterized by $T_N \ll T_K$ and $T_N \gg T_K$, respectively. In sufficiently low dimensions, $T_N \ll T_K$ and itinerant-electron magnetism appears in either an electron model such as the Hubbard model or a spin model such as the Heisenberg model. Magnetism in the RVB electron or spin liquid is a typical type of itinerant-electron magnetism. In sufficiently high dimensions, $T_N \gg T_K$ and local-moment magnetism appears in either an electron or spin model. Magnetism in infinite dimensions is a typical type of local-moment magnetism.

According to Eqs. (3.37) and (3.52), the possible mechanisms of the CW law are only the T dependences of $\tilde{\chi}_s(0)$, $J_Q(0, \mathbf{q})$, and $\Lambda(0, \mathbf{q})$. According to the self-consistent renormalization theory (SCR) of spin fluctuations,^{66–68} the mode-mode coupling term becomes smaller as T decreases in certain cases. If $\Lambda(0, \mathbf{q})$ decreases linearly against T as T decreases, the T dependence of $\Lambda(0, \mathbf{q})$ gives the CW law; the $\mathbf{q}$ dependence of $\Lambda(0, \mathbf{q})$ has to be small. If critical fluctuations develop as T decreases, $\Lambda(0, \mathbf{q})$ increases as T decreases and the T dependence of $\Lambda(0, \mathbf{q})$ suppresses the CW law, as in the Hubbard model on the square lattice. It is interesting to examine which occurs because of $\Lambda(0, \mathbf{q})$ in each actual system, the CW law or the suppression of the CW law.

If $T_N \ll T_K$ and $T_N < T \ll T_K$, $J_Q(0, \mathbf{q})$ increases almost linearly as T decreases in the two cases of $\mathbf{q} = 0$ and $\mathbf{q} = \mathbf{Q}_N$ discussed above. The T dependence of $J_Q(0, \mathbf{q})$ gives the CW law of itinerant-electron magnetism,^{33,40} which holds only for particular $\mathbf{q}$'s in the vicinity of the ordering wave number. If $T_N \gg T_K$ and $T > T_N$, the T dependence of $\tilde{\chi}_s(0)$ gives the CW law of local-moment magnetism, in which the Curie constant does not depend on $\mathbf{q}$ but the Weiss temperature depends on $\mathbf{q}$, as shown in Eq. (5.14).

Either the mechanism due to the T dependence of $J_Q(0, \mathbf{q})$ for particular $\mathbf{q}$'s or that of the single-site $\tilde{\chi}_s(0)$ for any $\mathbf{q}$ is of the zeroth order in $1/D$. The mechanism due to the T dependence of $\Lambda(0, \mathbf{q})$ is of higher order in $1/D$.

5.5 Metal-insulator transitions in actual compounds

In a multiband model, not only antiferromagnetic order but also orbital order is possible. We assume that $T_c \gg T_K$, where T_c is the critical temperature of antiferromagnetic or orbital order. If $T > T_c$, then $T \gg T_K$, the entropy is $O(k_B \ln 2)$ per unit cell, and the static susceptibility obeys the CW law of local-moment magnetism. The paramagnetic phase at $T > T_c$ is simply the Mott insulator. The ordered phase at $T \leq T_c$ is the Néel state of local moment magnetism or the type of insulator proposed by Slater.⁵³

It is possible that T_K substantially depends on the symmetry or type of lattice and the lattice constant. An MI transition is possible in conjunction with such a lattice effect on T_K as a function of an appropriate parameter, such as T , $n(\mu)$ or doping, pressure, substitution, and so on, between a high- T_K metallic phase with $T_K \gg T$ on a type of lattice and a low- T_K insulating phase with $T_K \lesssim T$ on a different type of lattice or the same type of lattice but with a different lattice constant. If the antiferromagnetic or orbital order appears in the low- T_K insulating phase, it is the Néel state of local moment magnetism or the type of insulator proposed by Slater;⁵³ if not, it is the Mott insulator. It is expected that this type of MI transition can explain MI transitions observed in many compounds.⁶⁹ Similarly, an MM or insulator-insulator (II) transition is also possible as a function of an appropriate parameter due to the dependence of T_K on the parameter in conjunction with the lattice effect.

5.6 Normal state for studying low- T ordered phases

The RVB electron liquid studied in the present research is simply the *normal* state at $T > T_c$ for studying possible low- T ordered phases at $T \leq T_c$, such as the Néel state of itinerant-electron magnetism, which is of the zeroth order in $1/D$, and an anisotropic superconducting state, which is of higher order in $1/D$, and so on. The *normal* state proposed by Anderson² for high-temperature superconductivity in cuprate oxides has to be the RVB electron liquid studied in the present paper, rather than an exotic Fermi liquid. The study in the present research confirms the relevance of the normal state assumed in a previous theory of high-temperature superconductivity in cuprate oxides^{70–73} and in previous theories of itinerant-electron ferromagnetism³³ and antiferromagnetism;^{74,75} the Kondo energy or the effective Fermi energy in the previous theories has to be understood as that enhanced by the RVB mechanism, if the mechanism is crucial.

6. Conclusions

The Hubbard model is studied. Every irreducible physical property of the Hubbard model is decomposed into single-site and multisite properties. The single-site property can be mapped to a local property of the Anderson model that is self-consistently determined to satisfy the mapping condition. Every single-site property is equal to its corresponding property of the Anderson model. Certain local properties that are not single-site properties are also equal to their corresponding properties of the Anderson model; e.g., the density of state per unit cell of the Hubbard model, which is denoted by $\rho_\mu(\varepsilon)$, is equal to that of the Anderson model.

In the field theory, the superexchange interaction arises from the virtual exchange of a pair excitation of an electron in the upper Hubbard band and a hole in the lower Hubbard band. If the on-site repulsion is U and the transfer integral between nearest neighbors is $-t/\sqrt{D}$, where D is the dimensionality, the exchange interaction constant between nearest neighbors is J/D , where $J = -4t^2/U$. This J is in agreement with that given by the conventional derivation. The superexchange interaction is a multisite effect and is a higher-order effect in $1/D$.

The Kondo-lattice theory (KLT) is a perturbative theory based on the mapping to the Anderson model to include multisite terms in terms of intersite mutual interactions. Its *un-*

perturbed state is constructed through the mapping to the Anderson model; in principle, all the single-site terms are rigorously considered in it. The Kondo temperature or energy, T_K or $k_B T_K$, is defined through the Anderson model. If $T_K > 0$ K and T is so low that $T \ll T_K$, the *unperturbed* state is the normal Fermi liquid. Since every single-site term is of the zeroth order in $1/D$ and multisite terms are of higher order in $1/D$ except for certain types of the conventional Weiss mean field, KLT is also the $1/D$ expansion theory.

Since a gap never opens at a nonzero temperature T such that $T > T_c$, where T_c is 0 K for $D=1$ and is the highest critical temperature among possible ones for $D \geq 2$, the density of states $\rho_\mu(\varepsilon)$ is more or less nonzero at $T > T_c$. If more or less $\rho_\mu(\varepsilon) > 0$ or $\rho_\mu(0) > 0$ is seriously considered, $k_B T_K$ is also more or less nonzero. Nonzero $k_B T_K$ and $\rho_\mu(0)$ have to be self-consistently determined with multisite effects to satisfy the mapping condition.

Exactly and almost half-filled cases in the strong-coupling region of $U/|t| \gg 1$ in the grand canonical ensemble are studied on the basis of KLT. The number of electrons per unit cell is denoted by n . If $|n-1| \lesssim |t|/(DU)$, the resonating-valence-bond (RVB) mechanism is crucial. The Fock-type self-energy due to the superexchange interaction is the RVB self-energy. The Kondo energy is substantially enhanced by the RVB self-energy, so that $k_B T_K = O(|J|/D)$. If the dimensionality D is so small that $k_B T_c \ll |J|/D$, the low- T phase of $T_c < T \ll T_K$ is the RVB electron liquid, which is stabilized by the Kondo effect in conjunction with the RVB mechanism; the RVB electron liquid in one dimension is also the Tomonaga-Luttinger (TL) liquid or the RVB-TL liquid. The density of states $\rho_\mu(\varepsilon)$ of the RVB electron liquid has a three-peak structure with a narrow midband between the upper and lower Hubbard bands, which corresponds to the three-peak structure with the Kondo peak between two subpeaks in the Anderson model. The midband is on the chemical potential within the Hubbard pseudogap. The bandwidth of the midband is $O(k_B T_K)$, $O(|J|/D)$, or $O[t^2/(DU)]$; its spectral weight is $O[t^2/(DU^2)]$ per unit cell; and $\rho_\mu(0) = O(1/U)$. Since the midband almost disappears in the Heisenberg limit, the RVB electron liquid in the Heisenberg limit is a quasi-spin liquid. The quasi-spin liquid shows metallic conductivity.

According to previous studies of the Kondo effect, the local electron liquid in the Anderson model and the local spin liquid in the s - d model adiabatically continue to each other, although the local gauge symmetry does not exist in the Anderson model but exists in the s - d model. According to the scaling theory for the Anderson localization, if no symmetry breaking occurs at a metal-insulator transition, the metallic and insulating phases adiabatically continue to each other. On the basis of these previous studies and the study in the present paper, it is proposed that the RVB electron liquid in the Hubbard model and the RVB spin liquid in the Heisenberg model adiabatically continue to each other, although the local gauge symmetry does not exist in the Hubbard model and the conductivity of the RVB electron liquid is metallic, while the local gauge symmetry exists in the Heisenberg model and the conductivity of the RVB spin liquid is zero.

If $T \gtrsim T_K$, thermal spin fluctuations are more dominant than quantum spin fluctuations, local moments forms, and the entropy is as large as $k_B \ln 2$ per unit cell. The high- T phase where $T \gtrsim T_K$ is the Mott insulator. The Mott insulator, which

is a high- T phase with a large entropy, never contradicts the RVB liquid, which is a low- T phase with a small entropy.

According to the Bethe-ansatz solution, the half-filled ground state in the canonical ensemble in one dimension is Lieb and Wu's insulator. The insulating ground state never contradicts the RVB-TL liquid at $0 \text{ K} < T \ll |J|/k_B$ in the grand canonical ensemble. It is desirable to determine which is the half-filled ground state in the grand canonical ensemble in one dimension, Lieb and Wu's insulator, a type of insulator different from it, or the RVB-TL liquid.

Appendix A: Sum Rule for $\Delta(\varepsilon)$

We consider

$$F(\varepsilon + i0) = [\varepsilon + \mu - \epsilon_d - \Sigma_\sigma(\varepsilon + i0)] - 1/R_\sigma(\varepsilon + i0). \quad (\text{A.1})$$

According to the mapping condition of Eq. (3.12),

$$\text{Im} F(\varepsilon + i0) = -\Delta(\varepsilon). \quad (\text{A.2})$$

Since $\Delta \Sigma_\sigma(\varepsilon + i0, \mathbf{k}) \rightarrow 0$ as $\varepsilon \rightarrow \pm\infty$,

$$\lim_{\varepsilon \rightarrow \pm\infty} F(\varepsilon + i0) = (2t^2/\varepsilon) + O(1/\varepsilon^2). \quad (\text{A.3})$$

Since $F(\varepsilon + i0)$ is analytic in the upper-half complex plane, according to Eqs. (A.2) and (A.3),

$$\int_{-\infty}^{+\infty} d\varepsilon \Delta(\varepsilon) = 2\pi t^2. \quad (\text{A.4})$$

Appendix B: Theoretical Constraint for $1/\tilde{\phi}_1$

B.1 Lower limit of $1/\tilde{\phi}_1$

We assume that $U/|t| \gg 1$, $\mu = \mu_0$, and $T_c < T \ll T_K$. The density of states $\rho_\mu(\varepsilon)$ has a symmetric three-peak structure with the midband between the Hubbard bands.

We consider the contribution from the midband to the integration in Eq. (A.4). According to Eq. (3.42), $|\text{Im} \Sigma_\sigma(+i0)| = O(\tilde{\phi}_1 k_B T^2/T_K)$; it can be ignored for $T \ll T_K$. According to Eq. (4.24), since $\text{Re} R_\sigma(+i0) = 0$, $\Delta(0) = 1/[\pi \rho_\mu(0)]$. According to Eqs. (3.45) and (4.23c), $1/\rho_\mu(0) = O(\tilde{\phi}_1 k_B T_K)$ and $k_B T_K = O[t^2/(DU)]$, respectively. Then,

$$\Delta(0) = O[(\tilde{\phi}_1 t^2)/(DU)]. \quad (\text{B.1})$$

Since $\tilde{\phi}_1 \gg 1$, $\Delta(0)$ is large; $\Delta(\varepsilon)$ has to have a peak at $\varepsilon = 0$ in order to satisfy Eq. (A.4). Since the peak width is $O(k_B T_K)$ or $O[t^2/(DU)]$ and the peak height is given by (B.1), the contribution from the midband is as large as

$$\int_{-O(k_B T_K)}^{+O(k_B T_K)} d\varepsilon \Delta(\varepsilon) = O[\tilde{\phi}_1 t^4/(DU)^2]. \quad (\text{B.2})$$

According to the sum rule of Eq. (A.4), Eq. (B.2) has to be smaller than $2\pi t^2$. Then,

$$1/\tilde{\phi}_1 \geq O[t^2/(DU)^2]. \quad (\text{B.3})$$

We consider the contribution from the Hubbard bands to the integration in Eq. (A.4). Since $\rho_\mu(\varepsilon) = -(1/\pi) \text{Im} R_\sigma(\varepsilon + i0)$ has peaks at $\varepsilon \simeq \pm U/2$, $\text{Re} R_\sigma(\varepsilon + i0) = 0$ for $\varepsilon = \varepsilon_\pm \simeq \pm U/2$. The peak height and bandwidth are $\rho_\mu(\varepsilon_\pm) = O(1/|t|)$ and $W_H = O(|t|)$, respectively.⁹ According to Eq. (4.24), since $|\text{Im} \Sigma_\sigma(\varepsilon_\pm + i0)| = O(|t|)$, $\Delta(\varepsilon_\pm) = O(|t|)$. The contribution from the Hubbard bands is as large as $\Delta(\varepsilon_\pm) W_H = O(t^2)$, which is consistent with Eq. (A.4).

B.2 Asymptotic behavior of $1/\tilde{\phi}_1$

We consider $\Delta(\varepsilon)$ defined by Eq. (3.7). It is given in terms of $V_{\mathbf{k}}$ and $E_c(\mathbf{k})$. Within KLT, it can be assumed without the loss of generality that $V_{\mathbf{k}}$ is constant: $V_{\mathbf{k}} = V$. Then,

$$\Delta(\varepsilon) = \pi|V|^2 \rho_c(\varepsilon), \quad (\text{B}\cdot 4)$$

$$\rho_c(\varepsilon) = \frac{1}{L} \sum_{\mathbf{k}} \delta[\varepsilon + \tilde{\mu} - E_c(\mathbf{k})]. \quad (\text{B}\cdot 5)$$

According to the sum rule of Eq. (A\cdot 4),

$$\pi|V|^2 = 2t^2. \quad (\text{B}\cdot 6)$$

In the s - d or Heisenberg limit of $U/|t| \rightarrow +\infty$, with $J = -4t^2/U$ kept constant, the Anderson model can be mapped to the s - d model with the s - d exchange interaction constant of

$$\tilde{J}_{s-d} = -4|V|^2/U = -(8/\pi)(t^2/U). \quad (\text{B}\cdot 7)$$

The dimensionless coupling constant is given by

$$\tilde{g}(\varepsilon) = \tilde{J}_{s-d} \tilde{\rho}_c(\varepsilon) = -[4/(\pi U)] \Delta(\varepsilon). \quad (\text{B}\cdot 8)$$

If $\tilde{g}(\varepsilon)$ is constant as a function of ε , T_K is given by

$$k_B T_K = W_c e^{-1/|\tilde{g}(0)|}, \quad (\text{B}\cdot 9)$$

in the most-divergent approximation,⁷⁶ where W_c is a half of the conduction bandwidth.

The energy dependence of $\tilde{g}(\varepsilon)$ has to be seriously considered in the mapped s - d model. According to the scaling theory for the s - d model,^{35,77} high-energy processes substantially renormalize fixed-point or eventual low-energy properties, but they can cause no symmetry breaking. Thus, whether the eventual $k_B T_K$ is zero or nonzero depends on whether the bare $\tilde{g}(0)$ is zero or nonzero. If $\tilde{g}(0) > 0$, the eventual $k_B T_K$ is nonzero; if $\tilde{g}(0) = 0$, the eventual $k_B T_K$ is zero.

According to Eqs. (B\cdot 1) and (B\cdot 8), it follows that

$$|\tilde{g}(0)| = O[\tilde{\phi}_1 t^2 / (DU^2)]. \quad (\text{B}\cdot 10)$$

If $|\tilde{g}(0)| \rightarrow 0$ as $U/|t| \rightarrow +\infty$, it is inconsistent with nonzero $k_B T_K$ in the Heisenberg limit; if $|\tilde{g}(0)| \rightarrow +\infty$ as $U/|t| \rightarrow +\infty$, it is inconsistent with Eq. (B\cdot 3). Since $k_B T_K = O(|J|/D)$, according to Eq. (B\cdot 9), $\tilde{g}(0)$ has to be the zeroth order in $1/D$. Since $|\tilde{g}(0)|$ has to be nonzero and finite in the limit of either $U/|t| \rightarrow +\infty$ or $1/D \rightarrow 0$,

$$1/\tilde{\phi}_1 = O[t^2 / (DU^2)]. \quad (\text{B}\cdot 11)$$

Appendix C: Proof of an Equality

There is a useful relationship between Ξ_D defined by Eq. (4.7) and $\pi_{xx}(0)$ defined by Eq. (4.33), as studied below. In the presence of magnetic impurities,

$$\begin{aligned} \Xi_D &= -\frac{1}{\pi L} \sum_{\mathbf{k}} \varphi_D(\mathbf{k}) \int_{-\infty}^{+\infty} d\varepsilon f_+(\varepsilon) \text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k}) \\ &= -\frac{\sqrt{D}}{\pi L} \sum_{\mathbf{k}} \cos(k_1 a) \int_{-\infty}^{+\infty} d\varepsilon f_+(\varepsilon) \text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k}), \end{aligned} \quad (\text{C}\cdot 1)$$

$$\begin{aligned} \pi_{xx}(0) &= \frac{2}{\pi L} \sum_{\mathbf{k}} \sin^2(k_1 a) \int_{-\infty}^{+\infty} d\varepsilon f_+(\varepsilon) [\text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k})] \\ &\quad \times [\text{Re} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k})]. \end{aligned} \quad (\text{C}\cdot 2)$$

Equation (C\cdot 1) is also given in the integration form by

$$\begin{aligned} \Xi_D &= \frac{\sqrt{D} a^D}{\pi(2\pi)^D} \int_{-\pi/a}^{+\pi/a} dk_1 \cdots \int_{-\pi/a}^{+\pi/a} dk_D \cos(k_1 a) \\ &\quad \times \int_{-\infty}^{+\infty} d\varepsilon f_+(\varepsilon) \text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k}). \end{aligned} \quad (\text{C}\cdot 3)$$

By the partial integration of Eq. (C\cdot 3) with respect to k_1 ,

$$\begin{aligned} \Xi_D &= 2t^* \frac{a^D}{\pi(2\pi)^D} \int_{-\pi/a}^{+\pi/a} dk_1 \cdots \int_{-\pi/a}^{+\pi/a} dk_D \sin^2(k_1 a) \\ &\quad \times \int_{-\infty}^{+\infty} d\varepsilon f_+(\varepsilon) [\text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k})] [\text{Re} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k})]. \end{aligned} \quad (\text{C}\cdot 4)$$

This is also given in the sum form by

$$\begin{aligned} \Xi_D &= 2t^* \frac{2}{\pi L} \sum_{\mathbf{k}} \sin^2(k_1 a) \int_{-\infty}^{+\infty} d\varepsilon f_+(\varepsilon) [\text{Im} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k})] \\ &\quad \times [\text{Re} \bar{g}_\sigma(\varepsilon + i0, \mathbf{k})]. \end{aligned} \quad (\text{C}\cdot 5)$$

It immediately follows that

$$\Xi_D = 2t^* \pi_{xx}(0). \quad (\text{C}\cdot 6)$$

Appendix D: On the Rigorousness of S³A

Not only all the single-site terms but also four types of the conventional Weiss mean field, which are multisite terms, are of the zeroth order in $1/D$: spin density wave or magnetism and orbital order,⁷⁸ which are possible for $U/|t| > 0$, and charge density wave and isotropic s -wave or BCS superconductivity, which are possible for $U/|t| < 0$. All the other multisite terms are of higher order in $1/D$. Since S³A can treat no conventional Weiss mean field or no symmetry breaking, S³A is not necessarily rigorous even in the limit $1/D \rightarrow 0$; it is expected that S³A will be rigorous in the limit $1/D \rightarrow 0$, if the Hilbert space is constrained within the subspace where no symmetry is allowed to be broken. The purpose of this Appendix is to examine whether S³A is rigorous in the limit $1/D \rightarrow 0$ within the Hilbert subspace. We consider the Hubbard model of Eq. (2.1); the absolute bandwidth of it is $4\sqrt{D}|t|$. We denote $\tilde{\phi}_1$ under S³A by $\tilde{\phi}_{S^3A}$, $\tilde{\phi}_{S^3A}(T)$, or $\tilde{\phi}_{S^3A}(D, T)$, depending on necessity or sufficiency; $\tilde{\phi}_1$ is used for that beyond S³A or that of KLT.

If $n(\mu) \neq 1$, the Mott insulator at $T = 0$ K is impossible either under or beyond S³A; $1/\tilde{\phi}_{S^3A} > 0$ and $1/\tilde{\phi}_1 > 0$. Since $1/\tilde{\phi}_1 \rightarrow 1/\tilde{\phi}_{S^3A} > 0$ as $1/D \rightarrow 0$, S³A is equivalent to KLT in the limit $1/D \rightarrow 0$ and rigorous in the limit $1/D \rightarrow 0$ within the Hilbert subspace. Then, the key issue is whether the Mott insulator is possible at $T = 0$ K for the half filling. In the following part, we assume the half filling in the canonical or grand canonical ensemble: $N = L$ or $n(\mu) = 1$.

There is a well-known scenario for the Mott insulator and transition, which is based on previous studies.⁷⁻¹⁰ If the absolute bandwidth is $4\sqrt{D}|t|$, the ground state is a metal for $U \lesssim 4\sqrt{D}|t|$ and is the Mott insulator at least for $U > 4\sqrt{D}|t|$. If $T = 0$ K, e.g., the Mott transition occurs at $U \simeq 4\sqrt{D}|t|$ as a function of U . A complete gap opens in the Mott insulator at $T = 0$ K; the gap is as large as $U - 4\sqrt{D}|t|$. The numerical study,²⁹ which is under S³A, confirms this scenario; in addition, it shows that hysteresis appears in the Mott transition. On the other hand, the study in Sect. 5.1, which is beyond S³A,

shows that what is stabilized in the nonzero and low- T phase of $0\text{ K} < T \ll |J|/(k_B D)$ for $U/|t| \gg 1$ is not the Mott insulator but the RVB liquid. The scenario is not relevant beyond S^3A , at least for $0\text{ K} < T \ll |J|/(k_B D)$. Since the RVB mechanism, which appears only beyond S^3A , is never considered in any stage or aspect of the scenario, it is expected that the scenario will be relevant only under S^3A , even if it is relevant. In the following part, we assume that $U > 4\sqrt{D}|t|$.

If the Mott insulator is possible at $T = 0\text{ K}$ in the canonical ensemble, it is possible only for $N = L$ but never for $N \neq L$. If so, and if the reservoir effect is only *implicitly* treated through the statistical average, the Mott insulator is also possible at $T = 0\text{ K}$ in the grand canonical ensemble; the insulator is *rigid* against the movement of μ . However, since the single-site $\Sigma_\sigma(\varepsilon + i0)$ has to have a pole at $\varepsilon = 0$ or just on μ , as discussed in Sect. 5.1, the Mott insulator cannot be *rigid* against the movement of μ . If the Mott insulator at $T = 0\text{ K}$ is possible, there is inconsistency between its possibility and *rigidity*. The inconsistency means or implies that the Mott insulator at $T = 0\text{ K}$ is impossible at least in the grand canonical ensemble, even if it is possible in the canonical ensemble. The critical argument given above is almost in parallel with that given in Sect. 5.2 against the possibility of Lieb and Wu's insulator. In the following part, we assume the grand canonical ensemble.

The Mott insulator at $T = 0\text{ K}$ is infinitely degenerate.¹³ In general, the ground state that is infinitely degenerate is unstable even against an infinitesimal perturbation; the third law of thermodynamics is mainly based on this fact. It is doubtful whether the Mott insulator at $T = 0\text{ K}$ is stable, particularly in the *explicit* presence of an electron reservoir. This critical argument can be confirmed at least in the simple reservoir model, as studied in Sect. 5.2.

Either of the two critical arguments above casts doubt that the well-known scenario is not relevant for $T = 0\text{ K}$, even under S^3A . We do not exclude another scenario that the Mott insulator is impossible at $T = 0\text{ K}$, even under S^3A .

If $T > 0\text{ K}$, more or less $\rho_\mu(0) > 0$; the single-site $\Sigma_\sigma(\varepsilon + i0)$ can have no pole on the real axis and can be expanded in the form of Eq. (3.42). Thus, more or less $1/\tilde{\phi}_{S^3A}(T) > 0$ for $T > 0$. If the ground state is the Mott insulator under S^3A , $1/\tilde{\phi}_{S^3A}(T) \rightarrow 0$ as $T \rightarrow 0\text{ K}$ and $1/\tilde{\phi}_{S^3A}(0\text{ K}) = 0$. If the ground state is a metal under S^3A , $1/\tilde{\phi}_{S^3A}(T) > 0$ for $T \geq 0\text{ K}$. On the other hand, if the RVB mechanism is considered, $1/\tilde{\phi}_1 = O[t^2/(DU^2)]$, as shown in Eq. (B·11). As the asymptotic behavior of $1/\tilde{\phi}_1$ as $U/|t| \rightarrow +\infty$ and $1/D \rightarrow 0$ beyond S^3A , it is reasonable to assume that

$$1/\tilde{\phi}_1 = \max\{O[t^2/(DU^2)], 1/\tilde{\phi}_{S^3A}(T)\}. \quad (\text{D} \cdot 1)$$

We call the limit of $1/D \rightarrow 0$ and $T \rightarrow 0\text{ K}$ a double limit. The issue to be studied is simply whether the double limit is unique; S^3A for $T = 0\text{ K}$ corresponds to the limit of $1/D \rightarrow 0$ followed by $T \rightarrow 0\text{ K}$ beyond S^3A .

First, we assume that the Mott insulator is possible at $T = 0\text{ K}$ under S^3A , following the well-known scenario: $1/\tilde{\phi}_{S^3A}(T) \rightarrow 0$ as $T \rightarrow 0\text{ K}$. If the double limit is taken in such a way that $t^2/(DU^2) \ll 1/\tilde{\phi}_{S^3A}(T)$ is kept satisfied, KLT is reduced to S^3A ; the Mott insulator is stabilized. If the double limit is taken in such a way that $t^2/(DU^2) \gg 1/\tilde{\phi}_{S^3A}(T)$ and $t^2/(DU^2) \gg k_B T$ are kept satisfied, KLT is not reduced to S^3A ; the RVB liquid is stabilized. The liquid is

an extremely bad metal with $k_B T_K(T) = O[t^2/(DU)] \rightarrow 0$, $1/\tilde{\phi}_1 = O[t^2/(DU^2)] \rightarrow 0$, and $\rho_\mu(0) = O(1/U) > 0$. Since there is a slight difference between the two types of limit, the double limit is not unique. Thus, S^3A is not necessarily equivalent to KLT in the limit $1/D \rightarrow 0$ nor necessarily rigorous even in the limit $1/D \rightarrow 0$ within the Hilbert subspace.

Next, we assume that the Mott insulator is impossible at $T = 0\text{ K}$ under S^3A , against the well-known scenario: $1/\tilde{\phi}_{S^3A}(D, T) > 0$ for $T \geq 0\text{ K}$. We consider, e.g., the case of $T = 0\text{ K}$. According to Eq. (D·1), a crossover D_c is defined by $t^2/(D_c U^2) = 1/\tilde{\phi}_{S^3A}(D_c, 0\text{ K})$; if $\tilde{\phi}_{S^3A}(D, 0\text{ K})$ depends on the reservoir efficiency δN defined by Eq. (5.3), D_c also depends on it, as will be discussed later. If $D \ll D_c$, the ground state is the RVB liquid; $k_B T_K(0\text{ K}) = O[t^2/(DU)]$ and $\rho_\mu(0) = O(1/U)$. If $D \gg D_c$, the ground state is the normal Fermi liquid in which the RVB mechanism is not crucial; $k_B T_K(0\text{ K}) = O[t/\tilde{\phi}_{S^3A}(D, 0\text{ K})]$ and $\rho_\mu(0)$ is simply given by that for $U = 0$. As a function of U , $\rho_\mu(0)$ is not monotonous and is minimal at approximately U such that $t^2/(DU^2) = 1/\tilde{\phi}_{S^3A}(D, 0\text{ K})$; as a function of D , $\rho_\mu(0)$ is almost constant for $D \lesssim D_c$, an increasing function for D such that $D \gtrsim D_c$ but not $D \gg D_c$, and almost constant for $D \gg D_c$. It is easy to show that the double limit is unique. Thus, S^3A is equivalent to KLT in the limit $1/D \rightarrow 0$ and rigorous in the limit $1/D \rightarrow 0$ within the Hilbert subspace.

If the reservoir effect is only *implicitly* treated through the statistical average, $\delta N = 0$ for $T = 0\text{ K}$, unless the ground state is degenerate between different N states. If the Mott insulator is possible at $T = 0\text{ K}$ for $\delta N = 0$ under S^3A , $1/\tilde{\phi}_{S^3A}(0\text{ K}) > 0$ for $\delta N > 0$ and $1/\tilde{\phi}_{S^3A}(0\text{ K}) \rightarrow 0$ as $\delta N \rightarrow 0$ in the presence of an electron reservoir. If so, the crossover D_c depends on δN in such a way that $D_c \rightarrow +\infty$ as $\delta N \rightarrow 0$; S^3A is rigorous in the limit $1/D \rightarrow 0$ within the Hilbert subspace for $\delta N > 0$ but not for $\delta N = 0$.

We conclude this Appendix. Two critical arguments are given against the possibility of the Mott insulator at $T = 0\text{ K}$, in addition to those given in Sect. 5. Whether S^3A is rigorous in the limit $1/D \rightarrow 0$ within the constrained Hilbert subspace where no symmetry is allowed to be broken depends on whether the Mott insulator is possible at $T = 0\text{ K}$ for the half filling under S^3A . If possible, S^3A is not necessarily rigorous; if not, S^3A is rigorous. It is desirable to determine whether the Mott insulator is possible at $T = 0\text{ K}$ under S^3A , or the third law of thermodynamics can be broken under S^3A , particularly in the *explicit* presence of an electron reservoir.

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- 55) If the absolute bandwidth becomes infinite as $1/D \rightarrow 0$, as in the model of the present paper, $U_{c2}(0 \text{ K}) \rightarrow +\infty$ as $1/D \rightarrow 0$ even under S^3A .
- 56) The RVB self-energy $\Delta\Sigma_\sigma^{(\text{RVB})}(+i0, \mathbf{k})$ is formally $O(1/D)$ for almost all $\mathbf{k}$'s. Because of the D dependence of $\tilde{\phi}_1 = O(D)$, it is practically $O[(1/D)^0]$ for almost all $\mathbf{k}$'s. Since self-consistent $\tilde{\phi}_1$ depends on D , KLT is not a simple expansion scheme in terms of $1/D$.
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